



US00RE47257E

(19) **United States**
(12) **Reissued Patent**
Nathan et al.

(10) **Patent Number:** **US RE47,257 E**
(45) **Date of Reissued Patent:** **Feb. 26, 2019**

(54) **VOLTAGE-PROGRAMMING SCHEME FOR CURRENT-DRIVEN AMOLED DISPLAYS**

(71) Applicant: **Ignis Innovation Inc.**, Waterloo (CA)

(72) Inventors: **Arokia Nathan**, Cambridge (GB);
Richard I-Heng Huang, Waterloo (CA); **Stefan Alexander**, Elmira (CA)

(73) Assignee: **Ignis Innovation Inc.**, Waterloo, Ontario

(21) Appl. No.: **14/326,705**

(22) Filed: **Jul. 9, 2014**

Related U.S. Patent Documents

Reissue of:

(64) Patent No.: **8,232,939**
Issued: **Jul. 31, 2012**
Appl. No.: **13/396,375**
Filed: **Feb. 14, 2012**

U.S. Applications:

(63) Continuation of application No. 14/090,320, filed on Nov. 26, 2013, now Pat. No. Re. 45,291, which is an (Continued)

(30) Foreign Application Priority Data

Jun. 29, 2004 (CA) 2472671

(51) **Int. Cl.**
G09G 3/30 (2006.01)
G09G 3/3233 (2016.01)
(Continued)

(52) **U.S. Cl.**
CPC **G09G 3/3233** (2013.01); **G09G 3/3241** (2013.01); **G09G 3/3283** (2013.01);
(Continued)

(58) **Field of Classification Search**
CPC G09G 3/3233; G09G 3/3241; G09G 3/323;
G09G 3/3291; G09G 2320/06938
(Continued)

(56) References Cited

U.S. PATENT DOCUMENTS

3,506,851 A 4/1970 Polkinghorn et al.
3,774,055 A 11/1973 Bapat et al.
(Continued)

FOREIGN PATENT DOCUMENTS

CA 1 294 034 1/1992
CA 2 109 951 11/1992
(Continued)

OTHER PUBLICATIONS

Ahnood et al.: "Effect of threshold voltage instability on field effect mobility in thin film transistors deduced from constant current measurements"; dated Aug. 2009 (3 pages).
(Continued)

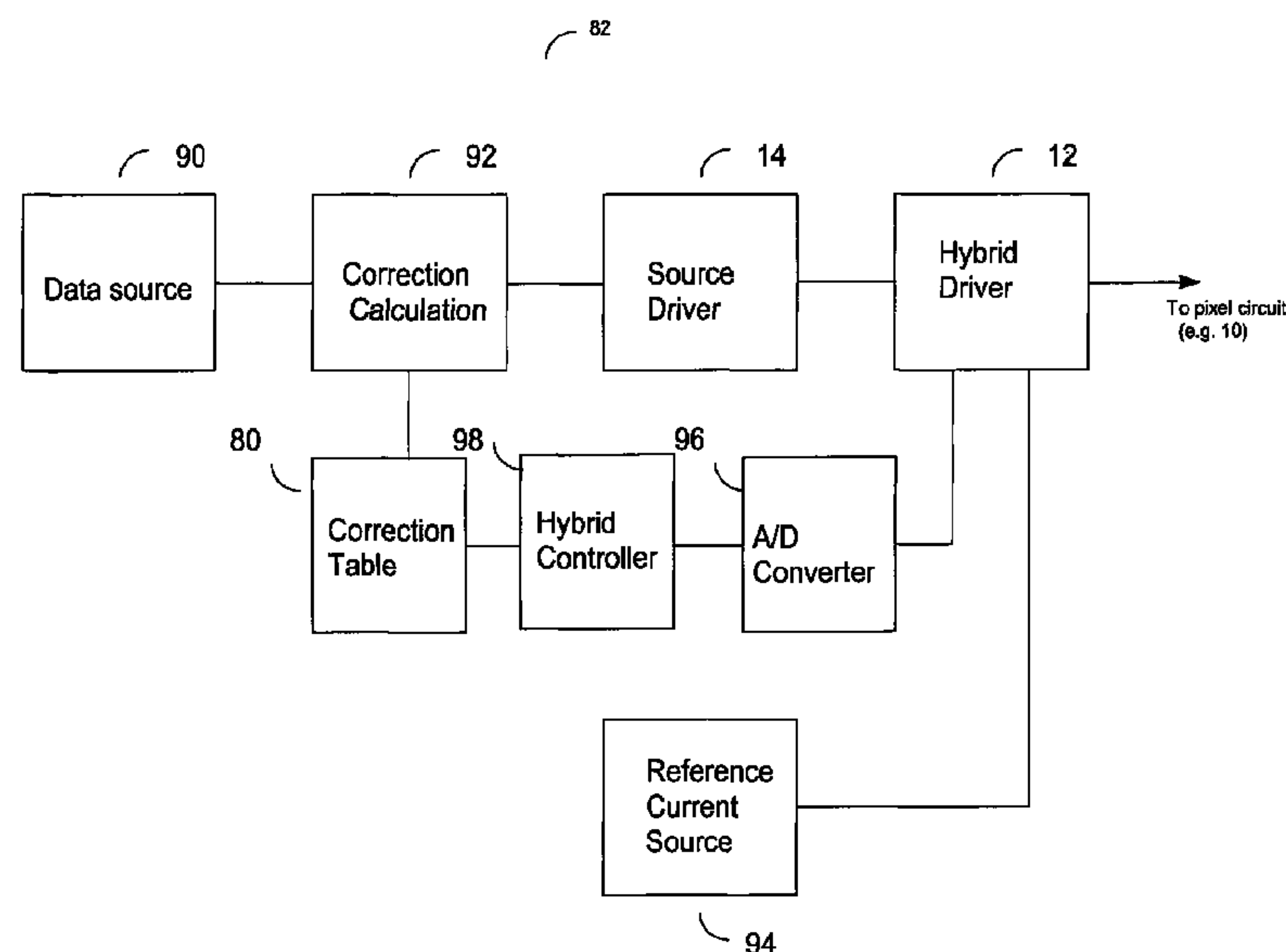
Primary Examiner — Adam L Basehoar

(74) *Attorney, Agent, or Firm* — Stratford Managers Corporation

(57) ABSTRACT

A system and method for driving an AMOLED display is provided. The AMOLED display includes a plurality of pixel circuits. A voltage-programming scheme, a current-programming scheme or a combination thereof is applied to drive the display. Threshold shift information, and/or voltage necessary to obtain hybrid driving circuit may be acquired. A data sampling may be implemented to acquire a current/voltage relationship. A feedback operation may be implemented to correct the brightness of the pixel.

5 Claims, 23 Drawing Sheets



Related U.S. Application Data

application for the reissue of Pat. No. 8,232,939, which is a continuation of application No. 11/571,480, filed as application No. PCT/CA2005/001007 on Jun. 28, 2005, now Pat. No. 8,115,707.

(51) Int. Cl.

G09G 3/3283 (2016.01)
G09G 3/3291 (2016.01)
G09G 3/3241 (2016.01)

(52) U.S. Cl.

CPC ... **G09G 3/3291** (2013.01); **G09G 2300/0842** (2013.01); **G09G 2300/0861** (2013.01); **G09G 2310/027** (2013.01); **G09G 2310/0251** (2013.01); **G09G 2320/0285** (2013.01); **G09G 2320/0295** (2013.01); **G09G 2320/043** (2013.01); **G09G 2320/0693** (2013.01)

(58) Field of Classification Search

USPC 345/77–80, 214
See application file for complete search history.

(56) References Cited

U.S. PATENT DOCUMENTS

4,090,096	A	5/1978	Nagami
4,160,934	A	7/1979	Kirsch
4,354,162	A	10/1982	Wright
4,758,831	A	7/1988	Kasahara et al.
4,943,956	A	7/1990	Noro
4,963,860	A	10/1990	Stewart
4,975,691	A	12/1990	Lee
4,996,523	A	2/1991	Bell et al.
5,051,739	A	9/1991	Hayashida et al.
5,153,420	A	10/1992	Hack et al.
5,198,803	A	3/1993	Shie et al.
5,204,661	A	4/1993	Hack et al.
5,206,633	A *	4/1993	Zalph 345/92
5,222,082	A	6/1993	Plus
5,266,515	A	11/1993	Robb et al.
5,489,918	A	2/1996	Mosier
5,498,880	A	3/1996	Lee et al.
5,572,444	A	11/1996	Lentz et al.
5,589,847	A	12/1996	Lewis
5,619,033	A	4/1997	Weisfield
5,648,276	A	7/1997	Hara et al.
5,670,973	A	9/1997	Bassetti et al.
5,686,935	A	11/1997	Weisbrod
5,691,783	A	11/1997	Numao et al.
5,712,653	A	1/1998	Katoh et al.
5,714,968	A	2/1998	Ikeda
5,723,950	A	3/1998	Wei et al.
5,744,824	A	4/1998	Kousai et al.
5,745,660	A	4/1998	Kolpatzik et al.
5,747,928	A	5/1998	Shanks et al.
5,748,160	A	5/1998	Shieh et al.
5,784,042	A	7/1998	Ono et al.
5,790,234	A	8/1998	Matsuyama
5,815,303	A	9/1998	Berlin
5,870,071	A	2/1999	Kawahata
5,874,803	A	2/1999	Garbuzov et al.
5,880,582	A	3/1999	Sawada
5,903,248	A	5/1999	Irwin
5,917,280	A	6/1999	Burrows et al.
5,923,794	A	7/1999	McGrath et al.
5,945,972	A	8/1999	Okumura et al.
5,949,398	A	9/1999	Kim
5,952,789	A	9/1999	Stewart et al.
5,952,991	A	9/1999	Akiyama et al.
5,982,104	A	11/1999	Sasaki et al.
5,990,629	A	11/1999	Yamada et al.
6,023,259	A	2/2000	Howard et al.
6,069,365	A	5/2000	Chow et al.
6,081,131	A	6/2000	Ishii

6,091,203	A	7/2000	Kawashima et al.
6,097,360	A	8/2000	Holloman
6,144,222	A	11/2000	Ho
6,157,583	A	12/2000	Starnes et al.
6,166,489	A	12/2000	Thompson et al.
6,177,915	B1	1/2001	Beeteson et al.
6,225,846	B1	5/2001	Wada et al.
6,229,506	B1	5/2001	Dawson et al.
6,229,508	B1	5/2001	Kane
6,232,939	B1	5/2001	Saito et al.
6,246,180	B1	6/2001	Nishigaki
6,252,248	B1	6/2001	Sano et al.
6,259,424	B1	7/2001	Kurogane
6,262,589	B1	7/2001	Tamukai
6,271,825	B1	8/2001	Greene et al.
6,274,887	B1	8/2001	Yamazaki et al.
6,288,696	B1	9/2001	Holloman
6,300,928	B1	10/2001	Kim
6,303,963	B1	10/2001	Ohtani et al.
6,304,039	B1	10/2001	Appelberg et al.
6,306,694	B1	10/2001	Yamazaki et al.
6,307,322	B1	10/2001	Dawson et al.
6,310,962	B1	10/2001	Chung et al.
6,316,786	B1	11/2001	Mueller et al.
6,320,325	B1	11/2001	Cok et al.
6,323,631	B1	11/2001	Juang
6,323,832	B1	11/2001	Nishizawa et al.
6,345,085	B1	2/2002	Yeo et al.
6,348,835	B1	2/2002	Sato et al.
6,356,029	B1	3/2002	Hunter
6,365,917	B1	4/2002	Yamazaki
6,373,453	B1	4/2002	Yudasaka
6,373,454	B1	4/2002	Knapp et al.
6,384,427	B1	5/2002	Yamazaki et al.
6,392,617	B1	5/2002	Gleason
6,399,988	B1	6/2002	Yamazaki
6,414,661	B1	7/2002	Shen et al.
6,417,825	B1	7/2002	Stewart et al.
6,420,758	B1	7/2002	Nakajima
6,420,834	B2	7/2002	Yamazaki et al.
6,420,988	B1	7/2002	Azami et al.
6,433,488	B1	8/2002	Bu
6,437,106	B1	8/2002	Stoner et al.
6,445,369	B1	9/2002	Yang et al.
6,445,376	B2	9/2002	Parrish
6,468,638	B2	10/2002	Jacobsen et al.
6,473,065	B1 *	10/2002	Fan 345/82
6,475,845	B2	11/2002	Kimura
6,489,952	B1	12/2002	Tanaka et al.
6,501,098	B2	12/2002	Yamazaki
6,501,466	B1	12/2002	Yamagishi et al.
6,512,271	B1	1/2003	Yamazaki et al.
6,518,594	B1	2/2003	Nakajima et al.
6,522,315	B2	2/2003	Ozawa et al.
6,524,895	B2	2/2003	Yamazaki et al.
6,525,683	B1	2/2003	Gu
6,531,713	B1	3/2003	Yamazaki
6,531,827	B2	3/2003	Kawashima
6,542,138	B1	4/2003	Shannon et al.
6,559,594	B2	5/2003	Fukunaga et al.
6,573,195	B1	6/2003	Yamazaki et al.
6,573,584	B1	6/2003	Nagakari et al.
6,576,926	B1	6/2003	Yamazaki et al.
6,577,302	B2	6/2003	Hunter et al.
6,580,408	B1	6/2003	Bae et al.
6,580,657	B2	6/2003	Sanford et al.
6,583,398	B2	6/2003	Harkin
6,583,775	B1	6/2003	Sekiya et al.
6,583,776	B2	6/2003	Yamazaki et al.
6,587,086	B1	7/2003	Koyama
6,593,691	B2	7/2003	Nishi et al.
6,594,606	B2	7/2003	Everitt
6,597,203	B2	7/2003	Forbes
6,611,108	B2	8/2003	Kimura
6,617,644	B1	9/2003	Yamazaki et al.
6,618,030	B2	9/2003	Kane et al.
6,639,244	B1	10/2003	Yamazaki et al.
6,641,933	B1	11/2003	Yamazaki et al.
6,661,180	B2	12/2003	Koyama

(56)

References Cited

U.S. PATENT DOCUMENTS

6,661,397 B2	12/2003	Mikami et al.	7,102,378 B2	9/2006	Kuo et al.
6,668,645 B1	12/2003	Gilmour et al.	7,106,285 B2	9/2006	Naugler
6,670,637 B2	12/2003	Yamazaki et al.	7,112,820 B2	9/2006	Chang et al.
6,677,713 B1	1/2004	Sung	7,116,058 B2	10/2006	Lo et al.
6,680,577 B1	1/2004	Inukai et al.	7,119,493 B2	10/2006	Fryer et al.
6,680,580 B1	1/2004	Sung	7,122,835 B1	10/2006	Ikeda et al.
6,687,266 B1	2/2004	Ma et al.	7,127,380 B1	10/2006	Iverson et al.
6,690,000 B1	2/2004	Muramatsu et al.	7,129,914 B2	10/2006	Knapp et al.
6,690,344 B1	2/2004	Takeuchi et al.	7,129,917 B2	10/2006	Yamazaki et al.
6,693,388 B2	2/2004	Oomura	7,141,821 B1	11/2006	Yamazaki et al.
6,693,610 B2	2/2004	Shannon et al.	7,164,417 B2	1/2007	Cok
6,697,057 B2	2/2004	Koyama et al.	7,193,589 B2	3/2007	Yoshida et al.
6,720,942 B2	4/2004	Lee et al.	7,199,516 B2	4/2007	Seo et al.
6,724,151 B2	4/2004	Yoo	7,220,997 B2	5/2007	Nakata
6,734,636 B2	5/2004	Sanford et al.	7,224,332 B2	5/2007	Cok
6,738,034 B2	5/2004	Kaneko et al.	7,227,519 B1	6/2007	Kawase et al.
6,738,035 B1	5/2004	Fan	7,235,810 B1	6/2007	Yamazaki et al.
6,753,655 B2	6/2004	Shih et al.	7,245,277 B2	7/2007	Ishizuka
6,753,834 B2	6/2004	Mikami et al.	7,248,236 B2	7/2007	Nathan et al.
6,756,741 B2	6/2004	Li	7,262,753 B2	8/2007	Tanghe et al.
6,756,952 B1	6/2004	Decaux et al.	7,264,979 B2	9/2007	Yamagata et al.
6,756,985 B1	6/2004	Hirotsune et al.	7,274,345 B2	9/2007	Imamura et al.
6,771,028 B1	8/2004	Winters	7,274,363 B2	9/2007	Ishizuka et al.
6,777,712 B2	8/2004	Sanford et al.	7,279,711 B1	10/2007	Yamazaki et al.
6,777,888 B2	8/2004	Kondo	7,304,621 B2	12/2007	Oomori et al.
6,780,687 B2	8/2004	Nakajima et al.	7,310,092 B2	12/2007	Imamura
6,781,567 B2	8/2004	Kimura	7,315,295 B2	1/2008	Kimura
6,806,497 B2	10/2004	Jo	7,317,429 B2	1/2008	Shirasaki et al.
6,806,638 B2	10/2004	Lin et al.	7,319,465 B2	1/2008	Mikami et al.
6,806,857 B2	10/2004	Sempel et al.	7,321,348 B2	1/2008	Cok et al.
6,809,706 B2	10/2004	Shimoda	7,339,560 B2	3/2008	Sun
6,815,975 B2	11/2004	Nara et al.	7,339,636 B2	3/2008	Voloschenko et al.
6,828,950 B2	12/2004	Koyama	7,355,574 B1	4/2008	Leon et al.
6,853,371 B2	2/2005	Miyajima et al.	7,358,941 B2	4/2008	Ono et al.
6,859,193 B1	2/2005	Yumoto	7,368,868 B2	5/2008	Sakamoto
6,861,670 B1	3/2005	Ohtani et al.	7,402,467 B1	7/2008	Kadono et al.
6,873,117 B2	3/2005	Ishizuka	7,411,571 B2	8/2008	Huh
6,873,320 B2	3/2005	Nakamura	7,414,600 B2	8/2008	Nathan et al.
6,876,346 B2	4/2005	Anzai et al.	7,423,617 B2	9/2008	Giraldo et al.
6,878,968 B1	4/2005	Ohnuma	7,432,885 B2	10/2008	Asano et al.
6,885,356 B2	4/2005	Hashimoto	7,474,285 B2	1/2009	Kimura
6,900,485 B2	5/2005	Lee	7,485,478 B2	2/2009	Yamagata et al.
6,903,734 B2	6/2005	Eu	7,502,000 B2	3/2009	Yuki et al.
6,909,114 B1	6/2005	Yamazaki	7,528,812 B2	5/2009	Tsuge et al.
6,909,243 B2	6/2005	Inukai	7,535,449 B2	5/2009	Miyazawa
6,909,419 B2	6/2005	Zavracky et al.	7,554,512 B2	6/2009	Steer
6,911,960 B1	6/2005	Yokoyama	7,569,849 B2	8/2009	Nathan et al.
6,911,964 B2	6/2005	Lee et al.	7,576,718 B2	8/2009	Miyazawa
6,914,448 B2	7/2005	Jinno	7,580,012 B2	8/2009	Kim et al.
6,919,871 B2	7/2005	Kwon	7,589,707 B2	9/2009	Chou
6,924,602 B2	8/2005	Komiya	7,609,239 B2	10/2009	Chang
6,937,215 B2	8/2005	Lo	7,619,594 B2	11/2009	Hu
6,937,220 B2	8/2005	Kitaura et al.	7,619,597 B2	11/2009	Nathan et al.
6,940,214 B1	9/2005	Komiya et al.	7,633,470 B2	12/2009	Kane
6,943,500 B2	9/2005	LeChevalier	7,656,370 B2	2/2010	Schneider et al.
6,947,022 B2	9/2005	McCartney	7,697,052 B1	4/2010	Yamazaki et al.
6,954,194 B2	10/2005	Matsumoto et al.	7,800,558 B2	9/2010	Routley et al.
6,956,547 B2 *	10/2005	Bae et al. 345/77	7,825,419 B2	11/2010	Yamagata et al.
6,975,142 B2	12/2005	Azami et al.	7,847,764 B2	12/2010	Cok et al.
6,975,332 B2	12/2005	Arnold et al.	7,859,492 B2	12/2010	Kohno
6,995,510 B2	2/2006	Murakami et al.	7,868,859 B2	1/2011	Tomida et al.
6,995,519 B2	2/2006	Arnold et al.	7,876,294 B2	1/2011	Sasaki et al.
7,022,556 B1	4/2006	Adachi	7,924,249 B2	4/2011	Nathan et al.
7,023,408 B2	4/2006	Chen et al.	7,932,883 B2	4/2011	Klompshouwer et al.
7,027,015 B2	4/2006	Booth, Jr. et al.	7,948,170 B2	5/2011	Striakhilev et al.
7,027,078 B2	4/2006	Reihl	7,969,390 B2	6/2011	Yoshida
7,034,793 B2	4/2006	Sekiya et al.	7,978,187 B2	7/2011	Nathan et al.
7,038,392 B2	5/2006	Libsch et al.	7,994,712 B2	8/2011	Sung et al.
7,057,359 B2	6/2006	Hung et al.	7,995,010 B2	8/2011	Yamazaki et al.
7,061,451 B2	6/2006	Kimura	8,026,876 B2	9/2011	Nathan et al.
7,064,733 B2	6/2006	Cok et al.	8,044,893 B2	10/2011	Nathan et al.
7,071,932 B2	7/2006	Libsch et al.	8,049,420 B2	11/2011	Tamura et al.
7,079,091 B2 *	7/2006	Kondakov et al. 345/76	8,077,123 B2	12/2011	Naugler, Jr.
7,088,051 B1	8/2006	Cok	8,115,707 B2	2/2012	Nathan et al.
7,088,052 B2	8/2006	Kimura	8,194,063 B2 *	6/2012	Levey G09G 3/3208 345/211
			8,223,177 B2	7/2012	Nathan et al.
			8,232,939 B2	7/2012	Nathan et al.
			8,259,044 B2	9/2012	Nathan et al.

(56)

References Cited

U.S. PATENT DOCUMENTS

8,264,431 B2	9/2012	Bulovic et al.	2003/0043088 A1	3/2003	Booth et al.
8,279,143 B2	10/2012	Nathan et al.	2003/0057895 A1	3/2003	Kimura
8,339,386 B2	12/2012	Leon et al.	2003/0058226 A1	3/2003	Bertram et al.
8,378,362 B2	2/2013	Heo et al.	2003/0062524 A1	4/2003	Kimura
8,493,295 B2	7/2013	Yamazaki et al.	2003/0063081 A1 *	4/2003	Kimura et al. 345/211
8,497,525 B2	7/2013	Yamagata et al.	2003/0071821 A1	4/2003	Sundahl et al.
8,514,212 B2 *	8/2013	Chou 345/211	2003/0076048 A1	4/2003	Rutherford
8,624,805 B2 *	1/2014	McCreary 345/80	2003/0090445 A1	5/2003	Chen et al.
2001/0002703 A1	6/2001	Koyama	2003/0090447 A1	5/2003	Kimura
2001/0004190 A1	6/2001	Nishi et al.	2003/0090481 A1	5/2003	Kimura
2001/0009283 A1	7/2001	Arao et al.	2003/0095087 A1	5/2003	Libsch
2001/0013806 A1	8/2001	Notani	2003/0107560 A1	6/2003	Yumoto et al.
2001/0015653 A1	8/2001	De Jong et al.	2003/0111966 A1	6/2003	Mikami et al.
2001/0020926 A1	9/2001	Kujik	2003/0122745 A1	7/2003	Miyazawa
2001/0024181 A1	9/2001	Kubota	2003/0122813 A1	7/2003	Ishizuki et al.
2001/0024186 A1	9/2001	Kane et al.	2003/0140958 A1	7/2003	Yang et al.
2001/0026127 A1	10/2001	Yoneda et al.	2003/0142088 A1	7/2003	LeChevalier
2001/0026179 A1	10/2001	Saeki	2003/0151569 A1	8/2003	Lee et al.
2001/0026257 A1	10/2001	Kimura	2003/0156101 A1	8/2003	Le Chevalier
2001/0026725 A1	10/2001	Petteruti et al.	2003/0169219 A1	9/2003	LeChevalier
2001/0030323 A1	10/2001	Ikeda	2003/0174152 A1	9/2003	Noguchi
2001/0033199 A1	10/2001	Aoki	2003/0179626 A1	9/2003	Sanford et al.
2001/0038098 A1	11/2001	Yamazaki et al.	2003/0197663 A1	10/2003	Lee et al.
2001/0040541 A1	11/2001	Yoneda et al.	2003/0206060 A1	11/2003	Suzuki
2001/0043173 A1	11/2001	Troutman	2003/0210256 A1	11/2003	Mori et al.
2001/0045929 A1	11/2001	Prache et al.	2003/0230141 A1	12/2003	Gilmour et al.
2001/0052606 A1	12/2001	Sempel et al.	2003/0230980 A1	12/2003	Forrest et al.
2001/0052898 A1	12/2001	Osame et al.	2003/0231148 A1	12/2003	Lin et al.
2001/0052940 A1	12/2001	Hagihara et al.	2004/0027063 A1	2/2004	Nishikawa
2002/0000576 A1	1/2002	Inukai	2004/0032382 A1	2/2004	Cok et al.
2002/0011796 A1	1/2002	Koyama	2004/0056604 A1	3/2004	Shih et al.
2002/0011799 A1	1/2002	Kimura	2004/0066357 A1	4/2004	Kawasaki
2002/0011981 A1	1/2002	Kuijk	2004/0070557 A1	4/2004	Asano et al.
2002/0012057 A1	1/2002	Kimura	2004/0070558 A1 *	4/2004	Cok et al. 345/76
2002/0014851 A1	2/2002	Tai et al.	2004/0070565 A1	4/2004	Nayar et al.
2002/0015031 A1	2/2002	Fujita et al.	2004/0080262 A1	4/2004	Park et al.
2002/0015032 A1	2/2002	Koyama et al.	2004/0080470 A1	4/2004	Yamazaki et al.
2002/0018034 A1	2/2002	Ohki et al.	2004/0090186 A1	5/2004	Kanauchi et al.
2002/0030190 A1	3/2002	Ohtani et al.	2004/0090400 A1 *	5/2004	Yoo 345/76
2002/0030528 A1	3/2002	Matsumoto et al.	2004/0095297 A1	5/2004	Libsch et al.
2002/0030647 A1	3/2002	Hack et al.	2004/0100427 A1	5/2004	Miyazawa
2002/0036463 A1	3/2002	Yoneda et al.	2004/0108518 A1	6/2004	Jo
2002/0047565 A1	4/2002	Nara et al.	2004/0113903 A1	6/2004	Mikami et al.
2002/0047852 A1	4/2002	Inukai et al.	2004/0129933 A1	7/2004	Nathan et al.
2002/0048829 A1	4/2002	Yamazaki et al.	2004/0130516 A1	7/2004	Nathan et al.
2002/0050795 A1	5/2002	Imura	2004/0135749 A1	7/2004	Kondakov et al.
2002/0052086 A1	5/2002	Maeda	2004/0145547 A1	7/2004	Oh
2002/0053401 A1	5/2002	Ishikawa et al.	2004/0150592 A1	8/2004	Mizukoshi et al.
2002/0067134 A1	6/2002	Kawashima	2004/0150594 A1	8/2004	Koyama et al.
2002/0070909 A1	6/2002	Asano et al.	2004/0150595 A1	8/2004	Kasai
2002/0080108 A1	6/2002	Wang	2004/0155841 A1	8/2004	Kasai
2002/0084463 A1	7/2002	Sanford et al.	2004/0174347 A1	9/2004	Sun et al.
2002/0101172 A1	8/2002	Bu	2004/0174349 A1	9/2004	Libsch
2002/0101433 A1	8/2002	McKnight	2004/0174354 A1	9/2004	Ono et al.
2002/0105279 A1	8/2002	Kimura	2004/0178743 A1	9/2004	Miller et al.
2002/0113248 A1	8/2002	Yamagata et al.	2004/0183759 A1	9/2004	Stevenson et al.
2002/0117722 A1	8/2002	Osada et al.	2004/0189627 A1	9/2004	Shirasaki et al.
2002/0122308 A1	9/2002	Ikeda	2004/0196275 A1	10/2004	Hattori
2002/0130686 A1	9/2002	Forbes	2004/0201554 A1	10/2004	Satoh
2002/0154084 A1	10/2002	Tanaka et al.	2004/0207615 A1	10/2004	Yumoto
2002/0158587 A1	10/2002	Komiya	2004/0239595 A1 *	12/2004	Vulto G09G 3/3208 345/76
2002/0158666 A1	10/2002	Azami et al.	2004/0239596 A1 *	12/2004	Ono et al. 345/76
2002/0158823 A1	10/2002	Zavracky et al.	2004/0246019 A1 *	12/2004	Nakano et al. 324/770
2002/0163314 A1	11/2002	Yamazaki et al.	2004/0252089 A1	12/2004	Ono et al.
2002/0167474 A1	11/2002	Everitt	2004/0257313 A1	12/2004	Kawashima et al.
2002/0180369 A1	12/2002	Koyama	2004/0257353 A1	12/2004	Imamura et al.
2002/0180721 A1	12/2002	Kimura et al.	2004/0257355 A1	12/2004	Naugler
2002/0186214 A1	12/2002	Siwinski	2004/0263437 A1	12/2004	Hattori
2002/0190332 A1	12/2002	Lee et al.	2004/0263444 A1	12/2004	Kimura
2002/0190924 A1	12/2002	Asano et al.	2004/0263445 A1	12/2004	Inukai et al.
2002/0190971 A1	12/2002	Nakamura et al.	2004/0263541 A1	12/2004	Takeuchi et al.
2002/0195967 A1	12/2002	Kim et al.	2005/0007355 A1	1/2005	Miura
2002/0195968 A1	12/2002	Sanford et al.	2005/0007357 A1	1/2005	Yamashita et al.
2003/0020413 A1	1/2003	Oomura	2005/0017650 A1	1/2005	Fryer et al.
2003/0030603 A1	2/2003	Shimoda	2005/0024081 A1	2/2005	Kuo et al.
			2005/0024393 A1	2/2005	Kondo et al.
			2005/0030267 A1	2/2005	Tanghe et al.
			2005/0035709 A1	2/2005	Furuie et al.

(56)

References Cited

U.S. PATENT DOCUMENTS

2005/0057484 A1 3/2005 Diefenbaugh et al.
 2005/0057580 A1 3/2005 Yamano et al.
 2005/0067970 A1 3/2005 Libsch et al.
 2005/0067971 A1 3/2005 Kane
 2005/0068270 A1* 3/2005 Awakura et al. 345/76
 2005/0068275 A1 3/2005 Kane
 2005/0073264 A1 4/2005 Matsumoto
 2005/0083323 A1 4/2005 Suzuki et al.
 2005/0088103 A1* 4/2005 Kageyama et al. 315/169.3
 2005/0093567 A1* 5/2005 Nara et al. 324/770
 2005/0110420 A1 5/2005 Arnold et al.
 2005/0110720 A1* 5/2005 Akimoto et al. 345/76
 2005/0110807 A1 5/2005 Chang
 2005/0117096 A1 6/2005 Voloschenko et al.
 2005/0140598 A1* 6/2005 Kim et al. 345/76
 2005/0140610 A1 6/2005 Smith et al.
 2005/0145891 A1 7/2005 Abe
 2005/0156831 A1 7/2005 Yamazaki et al.
 2005/0168416 A1* 8/2005 Hashimoto et al. 345/76
 2005/0179626 A1 8/2005 Yuki et al.
 2005/0179628 A1 8/2005 Kimura
 2005/0185200 A1 8/2005 Tobol
 2005/0200575 A1 9/2005 Kim et al.
 2005/0206590 A1 9/2005 Sasaki et al.
 2005/0219184 A1 10/2005 Zehner et al.
 2005/0225686 A1 10/2005 Brummack et al.
 2005/0248515 A1 11/2005 Naugler et al.
 2005/0260777 A1 11/2005 Brabec et al.
 2005/0269959 A1 12/2005 Uchino et al.
 2005/0269960 A1* 12/2005 Ono et al. 315/169.3
 2005/0280615 A1 12/2005 Cok et al.
 2005/0280766 A1 12/2005 Johnson et al.
 2005/0285822 A1 12/2005 Reddy et al.
 2005/0285825 A1 12/2005 Eom et al.
 2006/0001613 A1 1/2006 Routley et al.
 2006/0007072 A1 1/2006 Choi et al.
 2006/0012310 A1 1/2006 Chen et al.
 2006/0012311 A1 1/2006 Ogawa
 2006/0027807 A1 2/2006 Nathan et al.
 2006/0030084 A1* 2/2006 Young 438/149
 2006/0038758 A1 2/2006 Routley et al.
 2006/0038762 A1 2/2006 Chou
 2006/0066527 A1 3/2006 Chou
 2006/0066533 A1 3/2006 Sato et al.
 2006/0077135 A1 4/2006 Cok et al.
 2006/0082523 A1 4/2006 Guo et al.
 2006/0092185 A1 5/2006 Jo et al.
 2006/0097628 A1 5/2006 Suh et al.
 2006/0097631 A1 5/2006 Lee
 2006/0103611 A1 5/2006 Choi
 2006/0149493 A1 7/2006 Sambandan et al.
 2006/0170623 A1 8/2006 Naugler, Jr. et al.
 2006/0176250 A1 8/2006 Nathan et al.
 2006/0208961 A1 9/2006 Nathan et al.
 2006/0232522 A1 10/2006 Roy et al.
 2006/0244697 A1 11/2006 Lee et al.
 2006/0261841 A1 11/2006 Fish
 2006/0264143 A1 11/2006 Lee et al.
 2006/0273997 A1 12/2006 Nathan et al.
 2006/0284801 A1 12/2006 Yoon et al.
 2006/0284895 A1 12/2006 Marcu et al.
 2006/0290618 A1 12/2006 Goto
 2007/0001937 A1 1/2007 Park et al.
 2007/0001939 A1* 1/2007 Hashimoto et al. 345/76
 2007/0008268 A1 1/2007 Park et al.
 2007/0008297 A1 1/2007 Bassetti
 2007/0057873 A1 3/2007 Uchino et al.
 2007/0069998 A1 3/2007 Naugler et al.
 2007/0075727 A1 4/2007 Nakano et al.
 2007/0076226 A1 4/2007 Klompenhouwer et al.
 2007/0080905 A1* 4/2007 Takahara 345/76
 2007/0080906 A1 4/2007 Tanabe
 2007/0080908 A1 4/2007 Nathan et al.
 2007/0080918 A1 4/2007 Kawachi et al.
 2007/0097038 A1 5/2007 Yamazaki et al.

2007/0097041 A1 5/2007 Park et al.
 2007/0103419 A1 5/2007 Uchino et al.
 2007/0115221 A1 5/2007 Buchhauser et al.
 2007/0182671 A1 8/2007 Nathan et al.
 2007/0236517 A1 10/2007 Kimpe
 2007/0241999 A1 10/2007 Lin
 2007/0273294 A1 11/2007 Nagayama
 2007/0285359 A1 12/2007 Ono
 2007/0290958 A1 12/2007 Cok
 2007/0296672 A1 12/2007 Kim et al.
 2008/0001525 A1 1/2008 Chao et al.
 2008/0001544 A1 1/2008 Murakami et al.
 2008/0036708 A1* 2/2008 Shirasaki et al. 345/76
 2008/0042942 A1* 2/2008 Takahashi 345/77
 2008/0042948 A1 2/2008 Yamashita et al.
 2008/0048951 A1 2/2008 Naugler, Jr. et al.
 2008/0055209 A1 3/2008 Cok
 2008/0074413 A1 3/2008 Ogura
 2008/0088549 A1 4/2008 Nathan et al.
 2008/0088648 A1 4/2008 Nathan et al.
 2008/0117144 A1 5/2008 Nakano et al.
 2008/0150847 A1 6/2008 Kim et al.
 2008/0158115 A1 7/2008 Cordes et al.
 2008/0231558 A1 9/2008 Naugler
 2008/0231562 A1 9/2008 Kwon
 2008/0252571 A1 10/2008 Hente et al.
 2008/0290805 A1 11/2008 Yamada et al.
 2008/0297055 A1 12/2008 Miyake et al.
 2009/0032807 A1 2/2009 Shinohara et al.
 2009/0058772 A1 3/2009 Lee
 2009/0160743 A1 6/2009 Tomida et al.
 2009/0174628 A1 7/2009 Wang et al.
 2009/0184901 A1 7/2009 Kwon
 2009/0195483 A1 8/2009 Naugler, Jr. et al.
 2009/0201281 A1 8/2009 Routley et al.
 2009/0213046 A1* 8/2009 Nam 345/76
 2010/0004891 A1 1/2010 Ahlers et al.
 2010/0039422 A1 2/2010 Seto
 2010/0060911 A1 3/2010 Marcu et al.
 2010/0079711 A1 4/2010 Tanaka
 2010/0165002 A1 7/2010 Ahn
 2010/0194670 A1 8/2010 Cok
 2010/0207960 A1 8/2010 Kimpe et al.
 2010/0277400 A1 11/2010 Jeong
 2010/0315319 A1 12/2010 Cok et al.
 2010/0328294 A1 12/2010 Sasaki et al.
 2011/0069051 A1 3/2011 Nakamura et al.
 2011/0069089 A1 3/2011 Kopf et al.
 2011/0074750 A1 3/2011 Leon et al.
 2011/0090210 A1 4/2011 Sasaki et al.
 2011/0149166 A1 6/2011 Botzas et al.
 2011/0227964 A1 9/2011 Chaji et al.
 2011/0273399 A1 11/2011 Lee
 2011/0293480 A1 12/2011 Mueller
 2012/0056558 A1 3/2012 Toshiya et al.
 2012/0056869 A1* 3/2012 Cha et al. 345/214
 2012/0062565 A1 3/2012 Fuchs et al.
 2012/0299978 A1 11/2012 Chaji
 2013/0027381 A1 1/2013 Nathan et al.
 2013/0032831 A1 2/2013 Chaji et al.
 2013/0057595 A1 3/2013 Nathan et al.

FOREIGN PATENT DOCUMENTS

CA 2 249 592 7/1998
 CA 2 368 386 9/1999
 CA 2 242 720 1/2000
 CA 2 354 018 6/2000
 CA 2 432 530 7/2002
 CA 2 436 451 8/2002
 CA 2 438 577 8/2002
 CA 2 483 645 12/2003
 CA 2 463 653 1/2004
 CA 2 498 136 3/2004
 CA 2 522 396 11/2004
 CA 2 443 206 3/2005
 CA 2 472 671 12/2005
 CA 2 567 076 1/2006
 CA 2 526 782 4/2006

(56)

References Cited

FOREIGN PATENT DOCUMENTS

CA	2 541 531	7/2006
CA	2 550 102	4/2008
CA	2 773 699	10/2013
CN	1381032	11/2002
CN	1448908	10/2003
CN	1760945	4/2006
CN	102656621	9/2012
DE	20 2006 005427	6/2006
EP	0 158 366	10/1985
EP	0 940 796	9/1999
EP	1 028 471	8/2000
EP	1 103 947	5/2001
EP	1 111 577	6/2001
EP	1 130 565 A1	9/2001
EP	1 184 833	3/2002
EP	1 194 013	3/2002
EP	1 194 013	4/2002
EP	1 310 939	5/2003
EP	1 335 430 A1	8/2003
EP	1 372 136	12/2003
EP	1 381 019	1/2004
EP	1 418 566	5/2004
EP	1 429 312 A	6/2004
EP	1 439 520	7/2004
EP	145 0341 A	8/2004
EP	1 465 143 A	10/2004
EP	1 467 408	10/2004
EP	1 469 448 A	10/2004
EP	1 517 290	3/2005
EP	1 521 203 A2	4/2005
EP	1 594 347	11/2005
EP	1 784 055 A2	5/2007
EP	1854338 A1	11/2007
EP	1 879 169 A1	1/2008
EP	1 879 172	1/2008
GB	2 205 431	12/1988
GB	2 389 951	12/2003
JP	1272298	10/1989
JP	4-042619	2/1992
JP	6-314977	11/1994
JP	8-340243	12/1996
JP	09 090405	4/1997
JP	10-153759	6/1998
JP	10-254410	9/1998
JP	11-202295	7/1999
JP	11-219146	8/1999
JP	11 231805	8/1999
JP	11-282419	10/1999
JP	2000-056847	2/2000
JP	2000-077192	3/2000
JP	2000-81607	3/2000
JP	2000-089198	3/2000
JP	2000-352941	12/2000
JP	2001-134217	5/2001
JP	2001-195014	7/2001
JP	2002-055654	2/2002
JP	2002-91376	3/2002
JP	2002-514320	5/2002
JP	2002-268576	9/2002
JP	2002-278513	9/2002
JP	2002-333862	11/2002
JP	2003-022035	1/2003
JP	2003-076331	3/2003
JP	2003-124519	4/2003
JP	2003-150082	5/2003
JP	2003-177709	6/2003
JP	2003177709	6/2003
JP	2003-271095	9/2003
JP	2003-308046	10/2003
JP	2003-317944	11/2003
JP	2004-004675	1/2004
JP	2004-145197	5/2004
JP	2004-287345	10/2004
JP	2005-057217	3/2005
JP	2007-65015	3/2007

JP	2008102335	5/2008
JP	4-158570	10/2008
KR	2004-0100887	12/2004
TW	342486	10/1998
TW	473622	1/2002
TW	485337	5/2002
TW	502233	9/2002
TW	538650	6/2003
TW	569173	1/2004
TW	1221268	9/2004
TW	200727247	7/2007
WO	WO 1994-25954	11/1994
WO	WO 1998-48403	10/1998
WO	WO 1999-48079	9/1999
WO	WO 2001-06484	1/2001
WO	WO 2001-27910 A1	4/2001
WO	WO 2001-63587 A2	8/2001
WO	03/063124	3/2002
WO	WO 2002-067327 A	8/2002
WO	WO 2003-001496 A1	1/2003
WO	03/034389	4/2003
WO	WO 2003-034389 A	4/2003
WO	WO 2003-058594 A1	7/2003
WO	WO 2003-063124	7/2003
WO	WO 2003-077231	9/2003
WO	WO 2003-105117	12/2003
WO	WO 2004-003877	1/2004
WO	WO 2004-025615 A	3/2004
WO	WO 2004-034364	4/2004
WO	WO 2004-047058	6/2004
WO	WO 2004-104975 A1	12/2004
WO	WO 2005-022498	3/2005
WO	WO 2005-022500 A	3/2005
WO	WO 2005-029455	3/2005
WO	WO 2005-029456	3/2005
WO	WO 2005-055185	6/2005
WO	WO 2006-000101 A1	1/2006
WO	WO 2006-053424	5/2006
WO	2006/063448	6/2006
WO	WO 2006-063448 A	6/2006
WO	WO 2006-084360	8/2006
WO	WO 2006-137337	12/2006
WO	WO 2007-003877 A	1/2007
WO	WO 2007-079572	7/2007
WO	WO 2007-120849 A2	10/2007
WO	WO 2009-048618	4/2009
WO	WO 2009-055920	5/2009
WO	WO 2010-023270	3/2010
WO	WO 2011-041224 A1	4/2011
WO	WO 2011-046761 A1	6/2011
WO	WO 2011-067729	6/2011
WO	WO 2012-160424 A1	11/2012
WO	WO 2012-160471	11/2012
WO	WO 2012-164474 A2	12/2012
WO	WO 2012-164475 A2	12/2012

OTHER PUBLICATIONS

Alexander et al.: "Unique Electrical Measurement Technology for Compensation, Inspection, and Process Diagnostics of AMOLED HDTV"; dated May 2010 (4 pages).

Chaji et al.: "A Current-Mode Comparator for Digital Calibration of Amorphous Silicon AMOLED Displays"; dated Jul. 2008 (5 pages).

Chaji et al.: "A fast settling current driver based on the CCII for AMOLED displays"; dated Dec. 2009 (6 pages).

Chaji et al.: "A low-power high-performance digital circuit for deep submicron technologies"; dated Jun. 2005 (4 pages).

Chaji et al.: "A novel a-Si:H AMOLED pixel circuit based on short-term stress stability of a-Si:H TFTs"; dated Oct. 2005 (3 pages).

Chaji et al.: "An Enhanced and Simplified Optical Feedback Pixel Circuit for AMOLED Displays"; dated Oct. 2006.

Chaji et al.: "Compensation technique for DC and transient instability of thin film transistor circuits for large-area devices"; dated Aug. 2008.

Chaji et al.: "eUTDSP: a design study of a new VLIW-based DSP architecture"; dated My 2003 (4 pages).

(56)

References Cited

OTHER PUBLICATIONS

Chaji et al.: "Fast and Offset-Leakage Insensitive Current-Mode Line Driver for Active Matrix Displays and Sensors"; dated Feb. 2009 (8 pages).

Chaji et al.: "Low-Cost AMOLED Television with Ignis Compensating Technology"; dated May 2008 (4 pages).

Chaji et al.: "Low-Power Low-Cost Voltage-Programmed a-Si:H AMOLED Display"; dated Jun. 2008 (5 pages).

Chaji et al.: "Merged phototransistor pixel with enhanced near infrared response and flicker noise reduction for biomolecular imaging"; dated Nov. 2008 (3 pages).

Chaji et al.: "Stable Pixel Circuit for Small-Area High-Resolution a-Si:H AMOLED Displays"; dated Oct. 2008 (6 pages).

Chaji et al.: "Stable RGBW AMOLED display with OLED degradation compensation using electrical feedback"; dated Feb. 2010 (2 pages).

European Search Report and Written Opinion for Application No. 08 86 5338 dated Nov. 2, 2011 (7 pages).

European Search Report for Application No. 10 00 0421, dated Mar. 26, 2012 (6 pages).

European Search Report for Application No. EP 01 11 22313 dated Sep. 14, 2005 (4 pages).

European Search Report for Application No. EP 04 78 6661, dated Mar. 9, 2009.

European Search Report for Application No. EP 05 75 9141, dated Oct. 30, 2009.

European Search Report for Application No. EP 05 81 9617 dated Jan. 30, 2009.

European Search Report for Application No. EP 05 82 1114, dated Mar. 27, 2009 (2 pages).

European Search Report for Application No. EP 06 70 5133 dated Jul. 18, 2008.

European Search Report for Application No. EP 06 72 1798 dated Nov. 12, 2009 (2 pages).

European Search Report for Application No. EP 07 71 0608 dated Mar. 19, 2010 (7 pages).

European Search Report for Application No. EP 07 71 9579 dated May 20, 2009.

European Search Report for Application No. EP 07 81 5784 dated Jul. 20, 2010 (2 pages).

European Search Report for Application No. EP 10 16 6143, dated Sep. 3, 2010 (2 pages).

European Search Report for Application No. EP 10 83 4294.0-1903, dated Apr. 8, 2013, (9 pages).

European Search Report for Application No. PCT/CA2006/000177 dated Jun. 2, 2006.

European Supplementary Search Report for Application No. EP 04 78 6662 dated Jan. 19, 2007 (2 pages).

Extended European Search Report for Application No. 11 73 9485.8 dated Aug. 6, 2013(14 pages).

Extended European Search Report for Application No. EP 09 73 3076.5, dated Apr. 27, 2011 (13 pages).

Extended European Search Report for Application No. EP 11 16 8677.0, dated Nov. 29, 2012, (13 page).

Extended European Search Report for Application No. EP 11 19 1641.7 dated Jul. 11, 2012 (14 pages).

Extended European Search Report for Application No. EP 14 15 8051.4, dated Jul. 29, 2014, (4 pages).

Fossum, Eric R.. "Active Pixel Sensors: Are CCD's Dinosaurs?" SPIE: Symposium on Electronic Imaging. Feb. 1, 1993 (13 pages).

Goh et al., "A New a-Si:H Thin-Film Transistor Pixel Circuit for Active-Matrix Organic Light-Emitting Diodes", IEEE Electron Device Letters, vol. 24, No. 9, Sep. 2003, pp. 583-585.

International Search Report for Application No. PCT/IB2014/060879, Canadian Intellectual Property Office, dated Jul. 17, 2014 (3 pages).

International Preliminary Report on Patentability for Application No. PCT/CA2005/001007 dated Oct. 16, 2006, 4 pages.

International Search Report for Application No. PCT/CA02/00180 dated Jul. 31, 2002 (3 pages).

International Search Report for Application No. PCT/CA2004/001741 dated Feb. 21, 2005.

International Search Report for Application No. PCT/CA2004/001742, Canadian Patent Office, dated Feb. 21, 2005 (2 pages).

International Search Report for Application No. PCT/CA2005/001007 dated Oct. 18, 2005.

International Search Report for Application No. PCT/CA2005/001844 dated Mar. 28, 2006 (2 pages).

International Search Report for Application No. PCT/CA2005/001897, dated Mar. 21, 2006 (2 pages).

International Search Report for Application No. PCT/CA2007/000652 dated Jul. 25, 2007.

International Search Report for Application No. PCT/CA2008/002307, dated Apr. 28, 2009 (3 pages).

International Search Report for Application No. PCT/CA2009/000501, dated Jul. 30, 2009 (4 pages).

International Search Report for Application No. PCT/CA2009/001769, dated Apr. 8, 2010 (3 pages).

International Search Report for Application No. PCT/IB2010/055481, dated Apr. 7, 2011, 3 pages.

International Search Report for Application No. PCT/IB2010/055486, dated Apr. 19, 2011, 5 pages.

International Search Report for Application No. PCT/IB2010/055541 filed Dec. 1, 2010, dated May 26, 2011; 5 pages.

International Search Report for Application No. PCT/IB2011/050502, dated Jun. 27, 2011 (6 pages).

International Search Report for Application No. PCT/IB2011/051103, dated Jul. 8, 2011, 3 pages.

International Search Report for Application No. PCT/IB2011/055135, Canadian Patent Office, dated Apr. 16, 2012 (5 pages).

International Search Report for Application No. PCT/IB2012/052372, dated Sep. 12, 2012 (3 pages).

International Search Report for Application No. PCT/IB2013/054251, Canadian Intellectual Property Office, dated Sep. 11, 2013; (4 pages).

International Search Report for Application No. PCT/IB2014/058244, Canadian Intellectual Property Office, dated Apr. 11, 2014; (6 pages).

International Search Report for Application No. PCT/IB2014/059409, Canadian Intellectual Property Office, dated Jun. 12, 2014 (4 pages).

International Search Report for Application No. PCT/IB2014/059753, Canadian Intellectual Property Office, dated Jun. 23, 2014; (6 pages).

International Search Report for Application No. PCT/JP02/09668, dated Dec. 3, 2002, (4 pages).

International Written Opinion for Application No. PCT/CA2004/001742, Canadian Patent Office, dated Feb. 21, 2005 (5 pages).

International Written Opinion for Application No. PCT/CA2005/001897, dated Mar. 21, 2006 (4 pages).

International Written Opinion for Application No. PCT/CA2009/000501 dated Jul. 30, 2009 (6 pages).

International Written Opinion for Application No. PCT/IB2010/055481, dated Apr. 7, 2011, 6 pages.

International Written Opinion for Application No. PCT/IB2010/055486, dated Apr. 19, 2011, 8 pages.

International Written Opinion for Application No. PCT/IB2010/055541, dated May 26, 2011; 6 pages.

International Written Opinion for Application No. PCT/IB2011/050502, dated Jun. 27, 2011 (7 pages).

International Written Opinion for Application No. PCT/IB2011/051103, dated Jul. 8, 2011, 6 pages.

International Written Opinion for Application No. PCT/IB2011/055135, Canadian Patent Office, dated Apr. 16, 2012 (5 pages).

International Written Opinion for Application No. PCT/IB2012/052372, dated Sep. 12, 2012 (6 pages).

International Written Opinion for Application No. PCT/IB2013/054251, Canadian Intellectual Property Office, dated Sep. 11, 2013; (5 pages).

International Written Opinion for Application No. PCT/IB2014/059409, Canadian Intellectual Property Office, dated Jun. 12, 2014 (5 pages).

(56)

References Cited

OTHER PUBLICATIONS

International Written Opinion for Application No. PCT/IB2014/059753, Canadian Intellectual Property Office, dated Jun. 12, 2014 (6 pages).

International Written Opinion for Application No. PCT/IB2014/060879, Canadian Intellectual Property Office, dated Jul. 17, 2014; (4 pages).

Jafarabadiashtiani et al.: "A New Driving Method for a-Si AMOLED Displays Based on Voltage Feedback"; dated 2005 (4 pages).

Kanicki, J., et al. "Amorphous Silicon Thin-Film Transistors Based Active-Matrix Organic Light-Emitting Displays." Asia Display: International Display Workshops, Sep. 2001 (pp. 315-318).

Karim, K. S., et al. "Amorphous Silicon Active Pixel Sensor Readout Circuit for Digital Imaging." IEEE: Transactions on Electron Devices. vol. 50, No. 1, Jan. 2003 (pp. 200-208).

Ma e y et al: "Organic Light-Emitting Diode/Thin Film Transistor Integration for foldable Displays" Conference record of the 1997 International display research conference and international workshops on LCD technology and emissive technology. Toronto, Sep. 15-19, 1997 (6 pages).

Machine English translation of JP 2002-333862, 49 pages.

Matsueda y et al.: "35.1: 2.5-in. AMOLED with Integrated 6-bit Gamma Compensated Digital Data Driver"; dated May 2004.

Mendes E., et al. "A High Resolution Switch-Current Memory Base Cell." IEEE: Circuits and Systems. vol. 2, Aug. 1999 (pp. 718-721).

Nathan et al., "Amorphous Silicon Thin Film Transistor Circuit Integration for Organic LED Displays on Glass and Plastic", IEEE Journal of Solid-State Circuits, vol. 39, No. 9, Sep. 2004, pp. 1477-1486.

Nathan et al.: "Call for papers second international workshop on compact thin-film transistor (TFT) modeling for circuit simulation"; dated Sep. 2009 (1 page).

Nathan et al.: "Thin film imaging technology on glass and plastic" ICM 2000, Proceedings of the 12th International Conference on Microelectronics, (IEEE Cat. No. 00EX453), Tehran Iran; dated Oct. 31-Nov. 2, 2000, pp. 11-14, ISBN: 964-360-057-2, p. 13, col. 1, line 11-48; (4 pages).

Office Action in Japanese patent application No. JP2006-527247 dated Mar. 15, 2010. (8 pages).

Office Action in Japanese patent application No. JP2007-545796 dated Sep. 5, 2011. (8 pages).

Office Action in Japanese patent application No. JP2012-541612 dated Jul. 15, 2014. (3 pages).

Office Action issued in Chinese Patent Application 200910246264.4 dated Jul. 5, 2013; 8 pages.

Partial European Search Report for Application No. EP 11 168 677.0, dated Sep. 22, 2011 (5 pages).

Partial European Search Report for Application No. EP 11 19 1641.7, dated Mar. 20, 2012 (8 pages).

Patent Abstracts of Japan, vol. 1997, No. 08, Aug. 29, 1997, & JP 09 090405 A, Apr. 4, 1997 Abstract.

Patent Abstracts of Japan, vol. 1999, No. 13, Nov. 30, 1999, & JP 11 231805 A, Aug. 27, 1999 Abstract.

Patent Abstracts of Japan, vol. 2000, No. 09, Oct. 13, 2000—JP 2000 172199 A, Jun. 3, 2000, abstract.

Patent Abstracts of Japan, vol. 2002, No. 03, Apr. 3, 2002 (Apr. 4, 2004 & JP 2001 318627 A (Semiconductor EnergyLab Do Ltd), Nov. 16, 2001, abstract, paragraphs '01331-01801, paragraph '01691, paragraph '01701, paragraph '01721 and figure 10.

Philipp: "Charge transfer sensing" Sensor Review, vol. 19, No. 2, Dec. 31, 1999 (1999-1231), 10 pages.

Safavian et al.: "3-TFT active pixel sensor with correlated double sampling readout circuit for real-time medical x-ray imaging"; dated Jun. 2006 (4 pages).

Safavian et al.: "A novel current scaling active pixel sensor with correlated double sampling readout circuit for real time medical x-ray imaging"; dated May 2007 (7 pages).

Safavian et al.: "A novel hybrid active-passive pixel with correlated double sampling CMOS readout circuit for medical x-ray imaging"; dated May 2008 (4 pages).

Safavian et al.: "Self-compensated a-Si:H detector with current-mode readout circuit for digital X-ray fluoroscopy"; dated Aug. 2005 (4 pages).

Safavian et al.: "TFT active image sensor with current-mode readout circuit for digital x-ray fluoroscopy [5969D-82]"; dated Sep. 2005 (9 pages).

Safavian et al.: "Three-TFT image sensor for real-time digital X-ray imaging"; dated Feb. 2, 2006 (2 pages).

Sanford, James L., et al., "4.2 TFT AMOLED Pixel Circuits and Driving Methods", SID 03 Digest, ISSN/0003, 2003, pp. 10-13.

Search Report for Taiwan Invention Patent Application No. 093128894 dated May 1, 2012. (1 page).

Search Report for Taiwan Invention Patent Application No. 94144535 dated Nov. 1, 2012. (1 page).

Singh, et al., "Current Conveyor: Novel Universal Active Block", Samriddhi, S-JPSET vol. I, Issue 1, 2010, pp. 41-48.

Smith, Lindsay I., "A tutorial on Principal Components Analysis," dated Feb. 26, 2001 (27 pages).

Spindler et al., System Considerations for RGBW OLED Displays, Journal of the SID 14/1, 2006, pp. 37-48.

Stewart M. et al., "polysilicon TFT technology for active matrix oled displays" IEEE transactions on electron devices, vol. 48, No. 5, dated May 2001 (7 pages).

Tatsuya Sasaoka et al., 24.4L; Late-News Paper: A 13.0-inch AM-Oled Display with Top Emitting Structure and Adaptive Current Mode Programmed Pixel Circuit (TAC)', SID 01 Digest, (2001), pp. 384-387.

Vygranenko et al.: "Stability of indium-oxide thin-film transistors by reactive ion beam assisted deposition"; dated 2009.

Wang et al.: "Indium oxides by reactive ion beam assisted evaporation: From material study to device application"; dated Mar. 2009 (6 pages).

Yi He et al., "Current-Source a-Si:H Thin Film Transistor Circuit for Active-Matrix Organic Light-Emitting Displays", IEEE Electron Device Letters, vol. 21, No. 12, Dec. 2000, pp. 590-592.

Yu, Jennifer: "Improve OLED Technology for Display", Ph.D. Dissertation, Massachusetts Institute of Technology, Sep. 2008 (151 pages).

Zhiguo Meng et al; "24.3: Active-Matrix Organic Light-Emitting Diode Display implemented Using Metal-Induced Unilaterally Crystallized Polycrystalline Silicon Thin-Film Transistors", SID 01 Digest, (2001), pp. 380-383.

Alexander et al.: "Pixel circuits and drive schemes for glass and elastic AMOLED displays"; dated Jul. 2005 (9 pages).

Ashtiani et al.: "AMOLED Pixel Circuit With Electronic Compensation of Luminance Degradation"; dated Mar. 2007 (4 pages).

Chaji et al.: "A Low-Cost Stable Amorphous Silicon AMOLED Display with Full V_T- and V_{O-L-E-D} Shift Compensation"; dated May 2007 (4 pages).

Chaji et al.: "A low-power driving scheme for a-Si:H active-matrix organic light-emitting diode displays"; dated Jun. 2005 (4 pages).

Chaji et al.: "A Novel Driving Scheme and Pixel Circuit for AMOLED Displays"; dated Jun. 2006 (4 pages).

Chaji et al.: "A novel driving scheme for high-resolution large-area a-Si:H AMOLED displays"; dated Aug. 2005 (4 pages).

Chaji et al.: "A Stable Voltage-Programmed Pixel Circuit for a-Si:H AMOLED Displays"; dated Dec. 2006 (12 pages).

Chaji et al.: "A Sub-μA fast-settling current-programmed pixel circuit for AMOLED displays"; dated Sep. 2007.

Chaji et al.: "Driving; scheme for stable operation of 2-TFT a-Si AMOLED pixel"; dated Apr. 2005 (2 pages).

Chaji et al.: "Dynamic-effect compensating technique for stable a-Si:H AMOLED displays"; dated Aug. 2005 (4 pages).

Chaji et al.: "Electrical Compensation of OLED Luminance Degradation"; dated Dec. 2007 (3 pages).

Chaji et al.: "High Speed Low Power Adder Design With A New Logic Style: Pseudo Dynamic Logic (SDL)"; dated Oct. 2001 (4 pages).

Chaji et al.: "High-precision, fast current source for large-area current-programmed a-Si flat panels"; dated Sep. 2006 (4 pages).

Chaji et al.: "Low-Cost Stable a-Si:H AMOLED Display for Portable Applications"; dated Jun. 2006 (4 pages).

(56)

References Cited

OTHER PUBLICATIONS

Chaji et al.: "Parallel Addressing Scheme for Voltage-Programmed Active-Matrix OLED Displays"; dated May 2007 (6 pages).

Chaji et al.: "Pseudo dynamic logic (SDL): a high-speed and low-power dynamic logic family"; dated 2002 (4 pages).

Chaji et al.: "Stable a-Si:H circuits based on short-term stress stability of amorphous silicon thin film transistors"; dated May 2006 (4 pages).

Chaji et al.: "Stable Pixel Circuit for Small-Area High-Resolution a-Si:H AMOLED Displays"; dated 2008 (7 pages).

Chaji et al.: "Thin-Film Transistor Integration for Biomedical Imaging and AMOLED Displays"; dated 2008 (177 pages).

International Search Report for International Application No. PCT/CA2005/001007 dated Oct. 18, 2005.

Jafarabadiashtiani et al.: "A New Driving Method for a-Si AMOLED Displays Based on Voltage Feedback"; May 27, 2005 (4 pages).

Lee et al.: "Ambipolar Thin-Film Transistors Fabricated by PECVD Nanocrystalline Silicon"; dated 2006 (6 pages).

Nathan et al.: "Backplane Requirements for Active Matrix Organic Light Emitting Diode Displays"; dated 2006 (16 pages).

Nathan et al.: "Driving schemes for a-Si and LTPS AMOLED displays"; dated Dec. 2005 (11 pages).

Nathan et al.: "Invited Paper: a-Si for AMOLED—Meeting the Performance and Cost Demands of Display Applications (Cell Phone to HDTV)"; dated 2006 (4 pages).

Rafati et al.: "Comparison of a 17 b multiplier in Dual-rail domino and in Dual-rail D L (D L) logic styles"; dated 2002 (4 pages).

International Preliminary Report on Patentability for International Application No. PCT/CA2005/001007 dated Oct. 16, 2006, 4 pages.

* cited by examiner

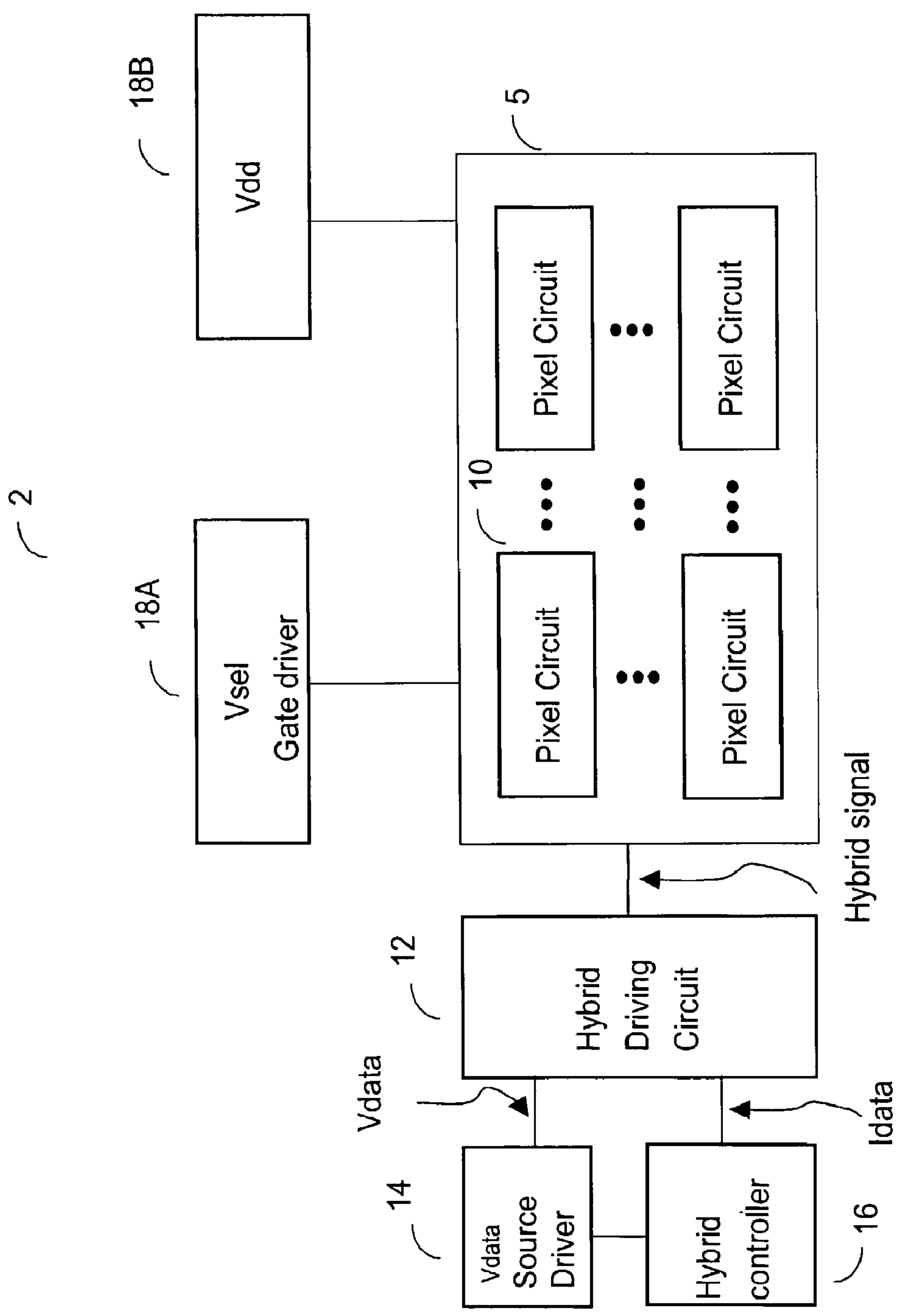


FIG.1

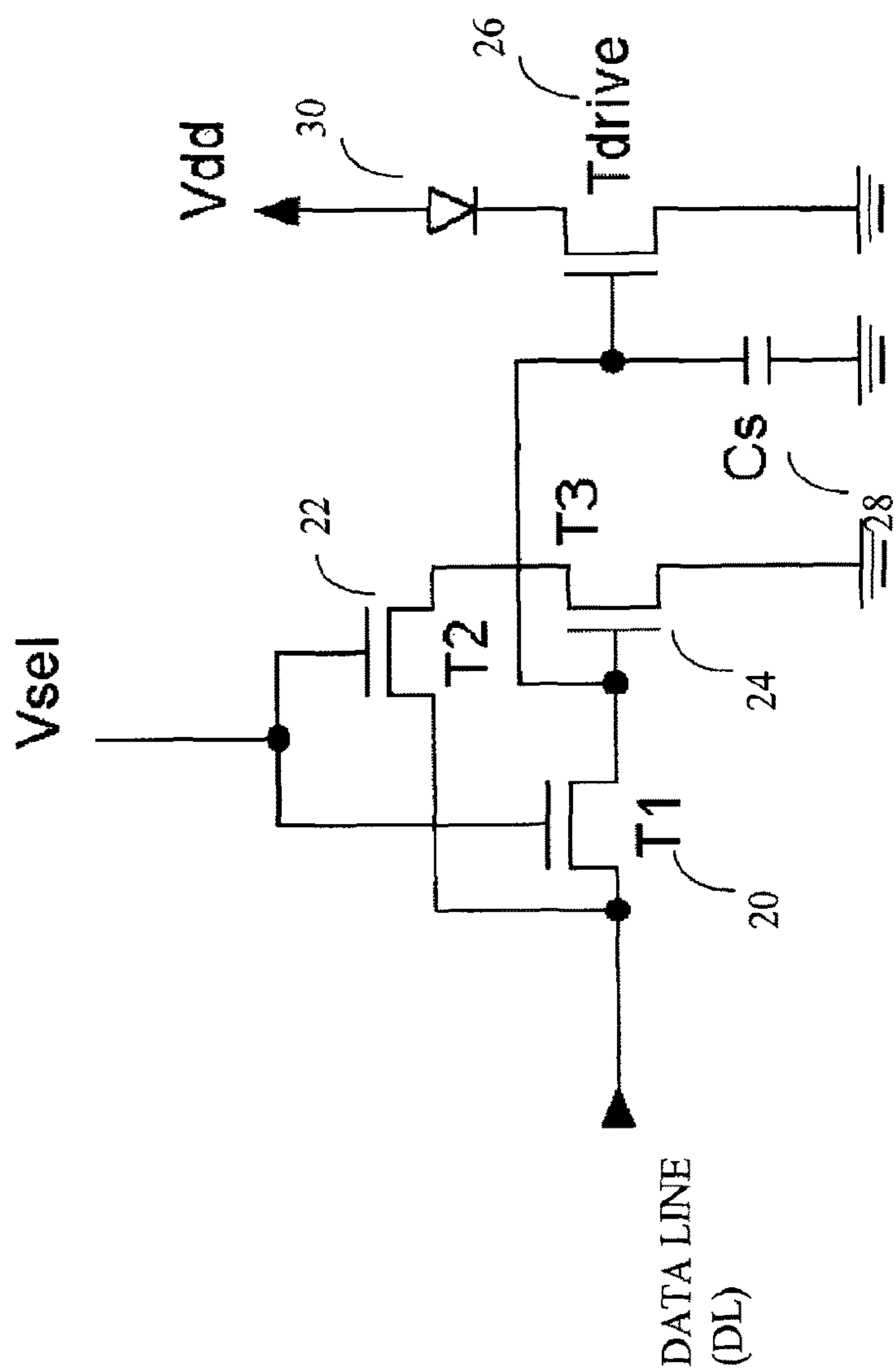


FIG.2

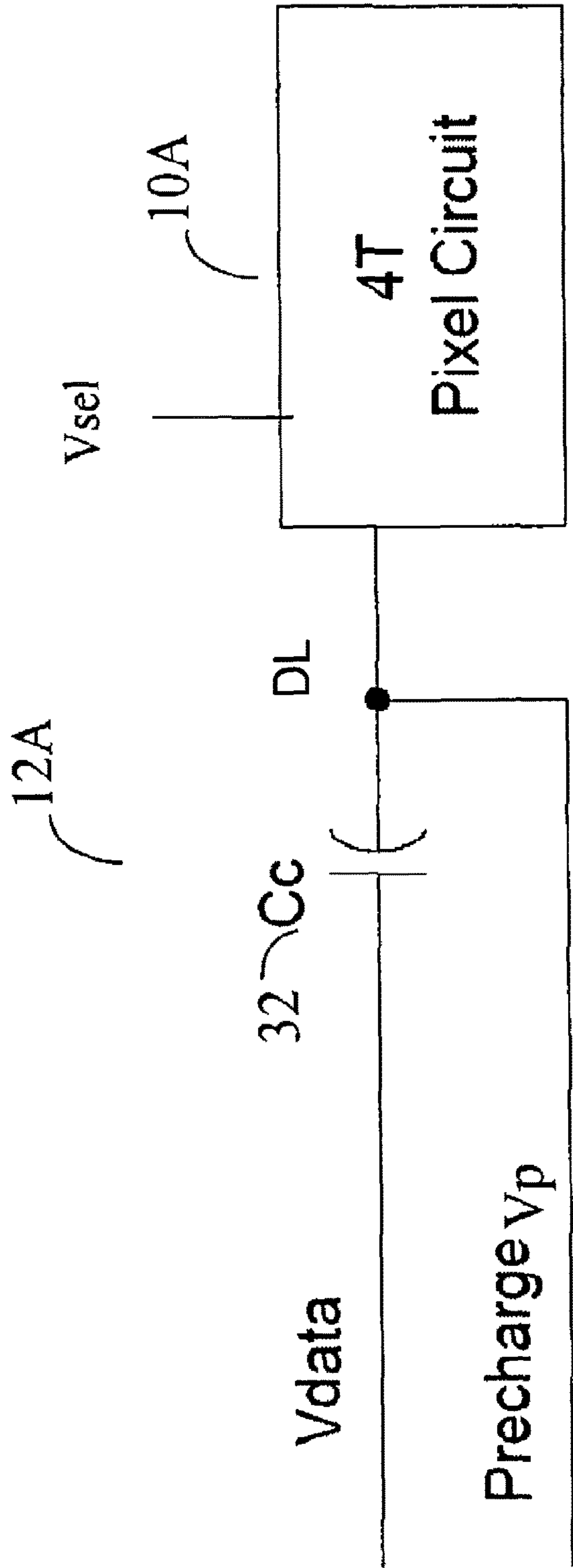


FIG.3

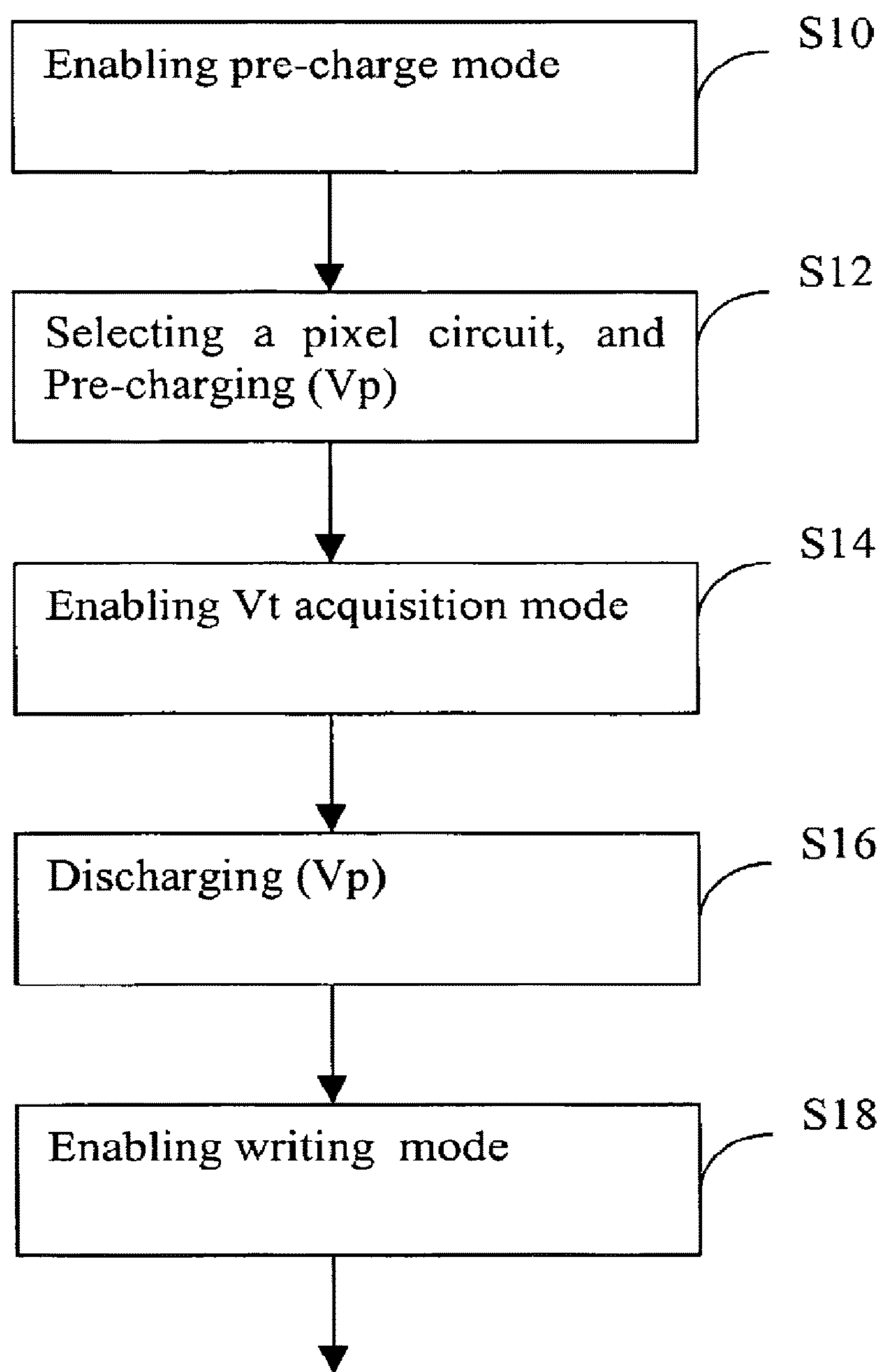


FIG. 4

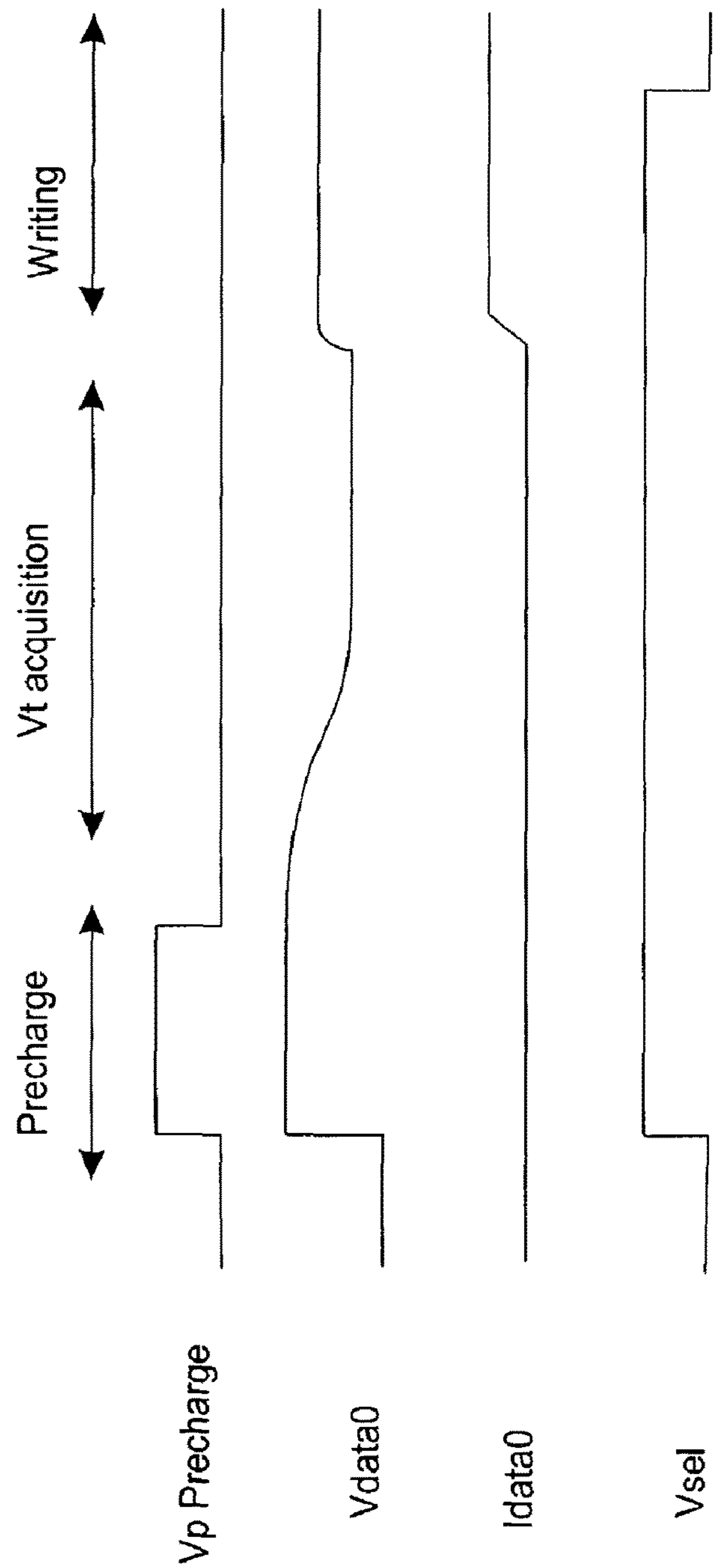


FIG.5

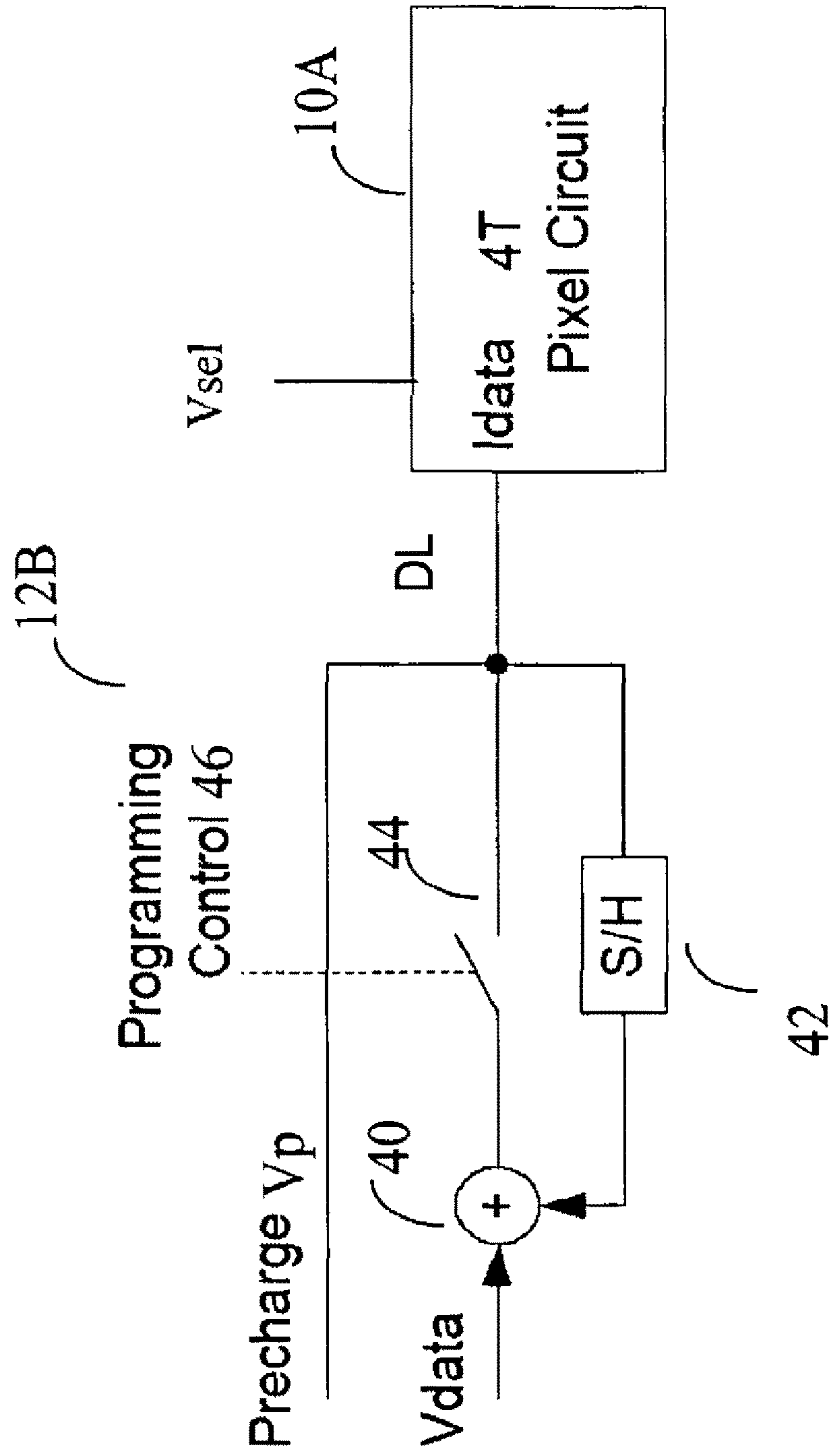


FIG.6

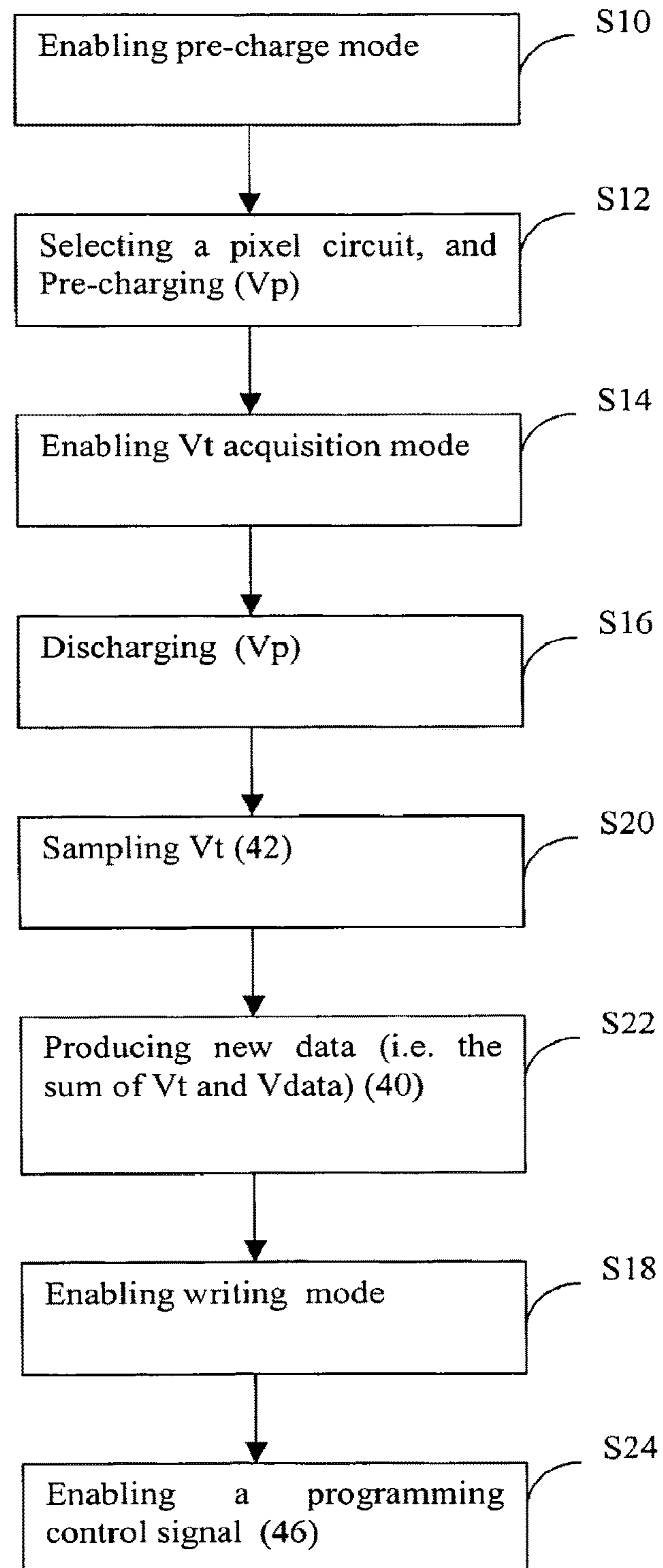


FIG. 7

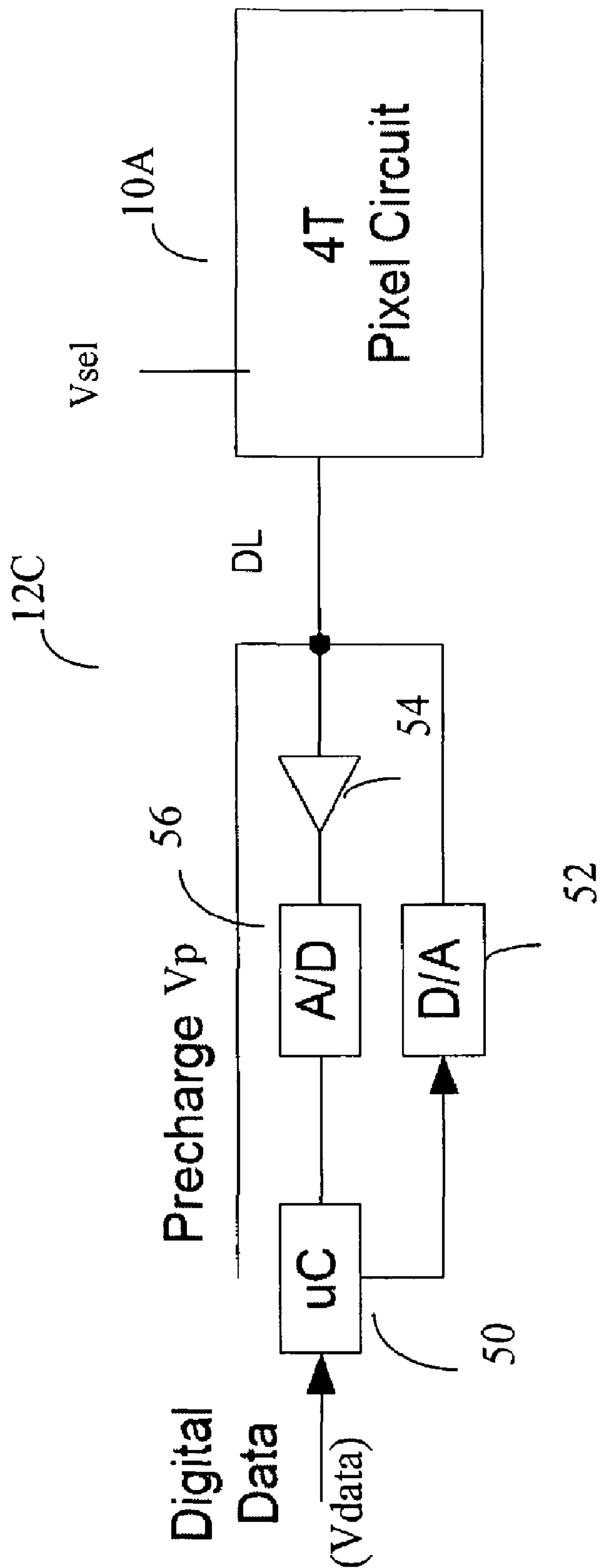


FIG.8

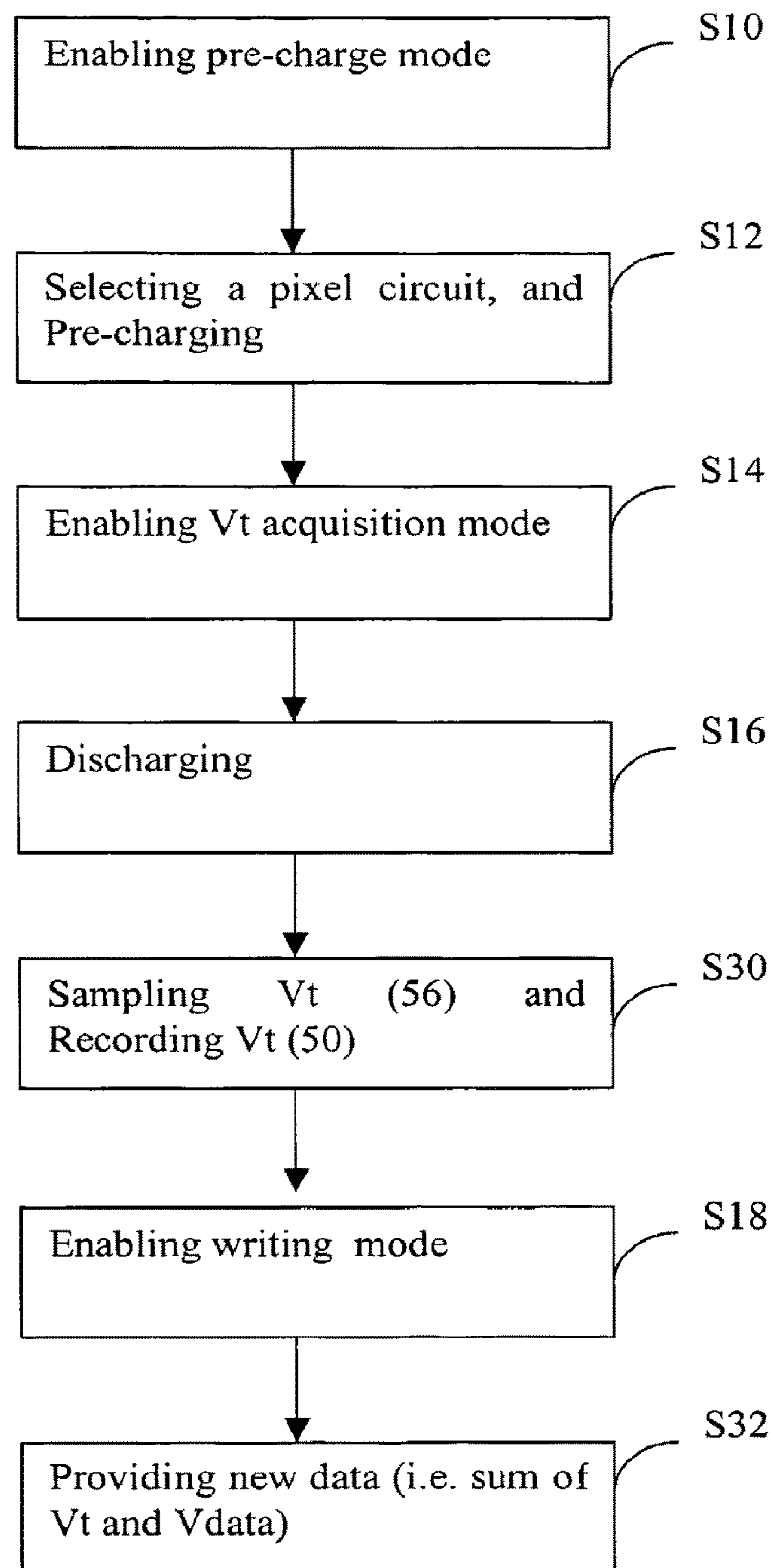


FIG. 9

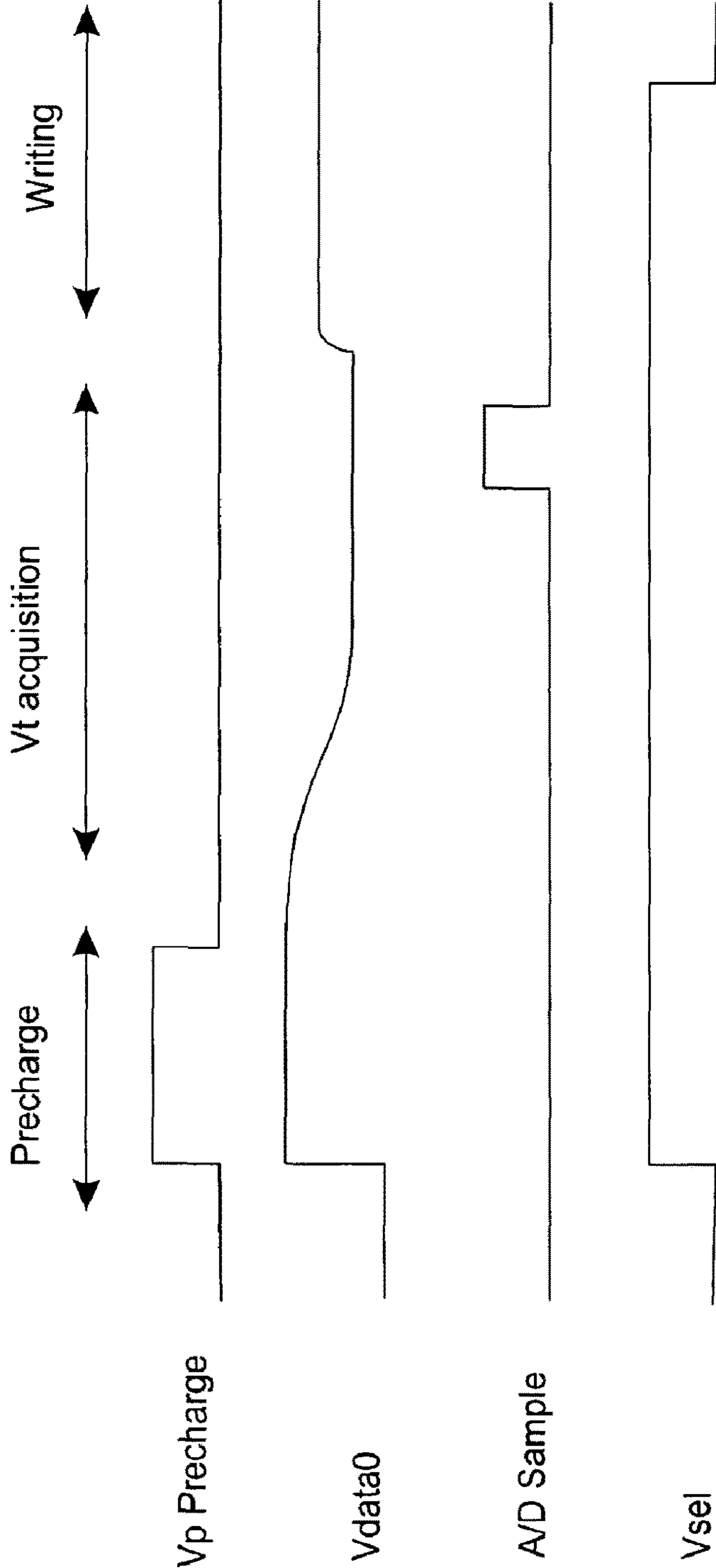


FIG.10

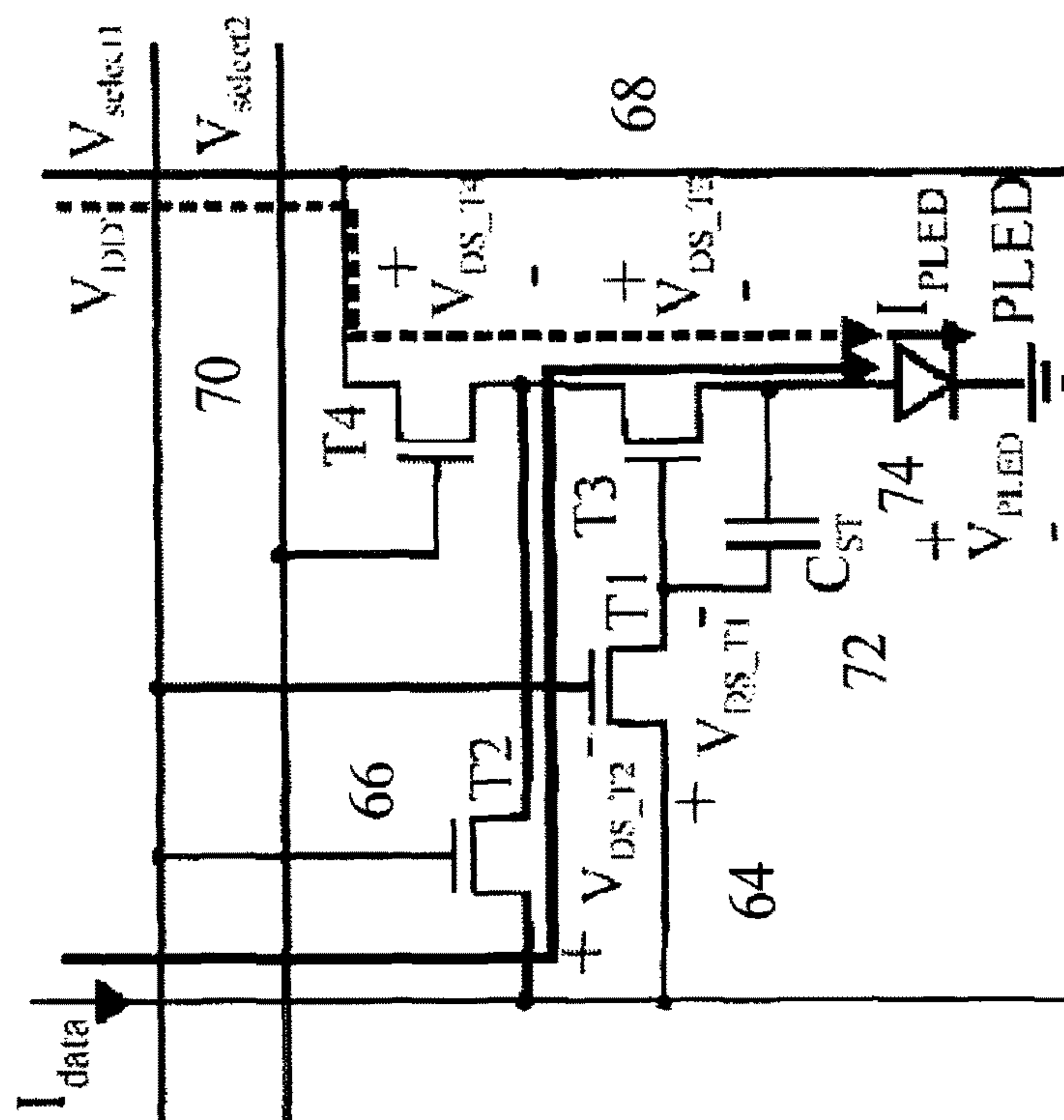


FIG. 11

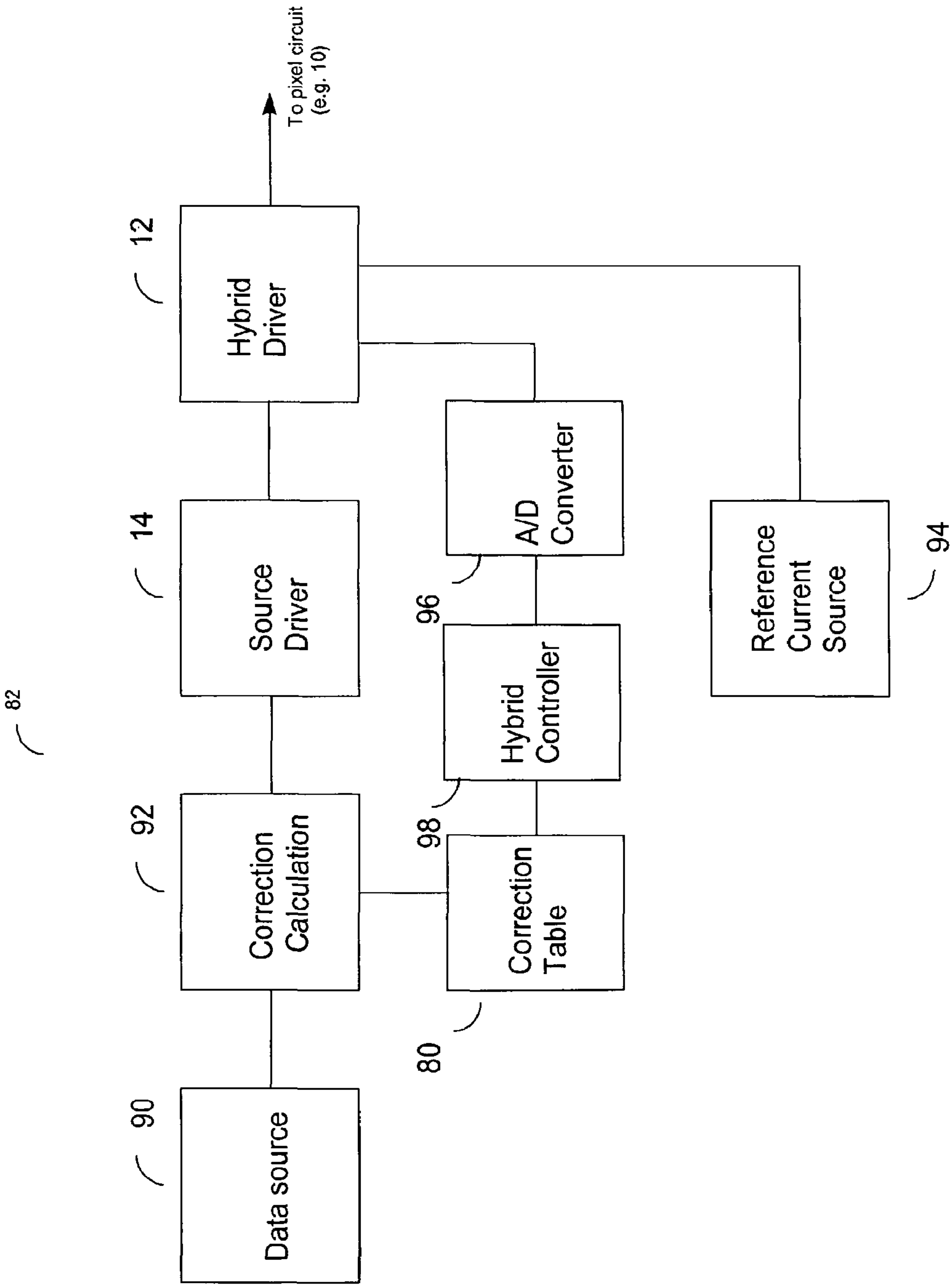


FIG. 12

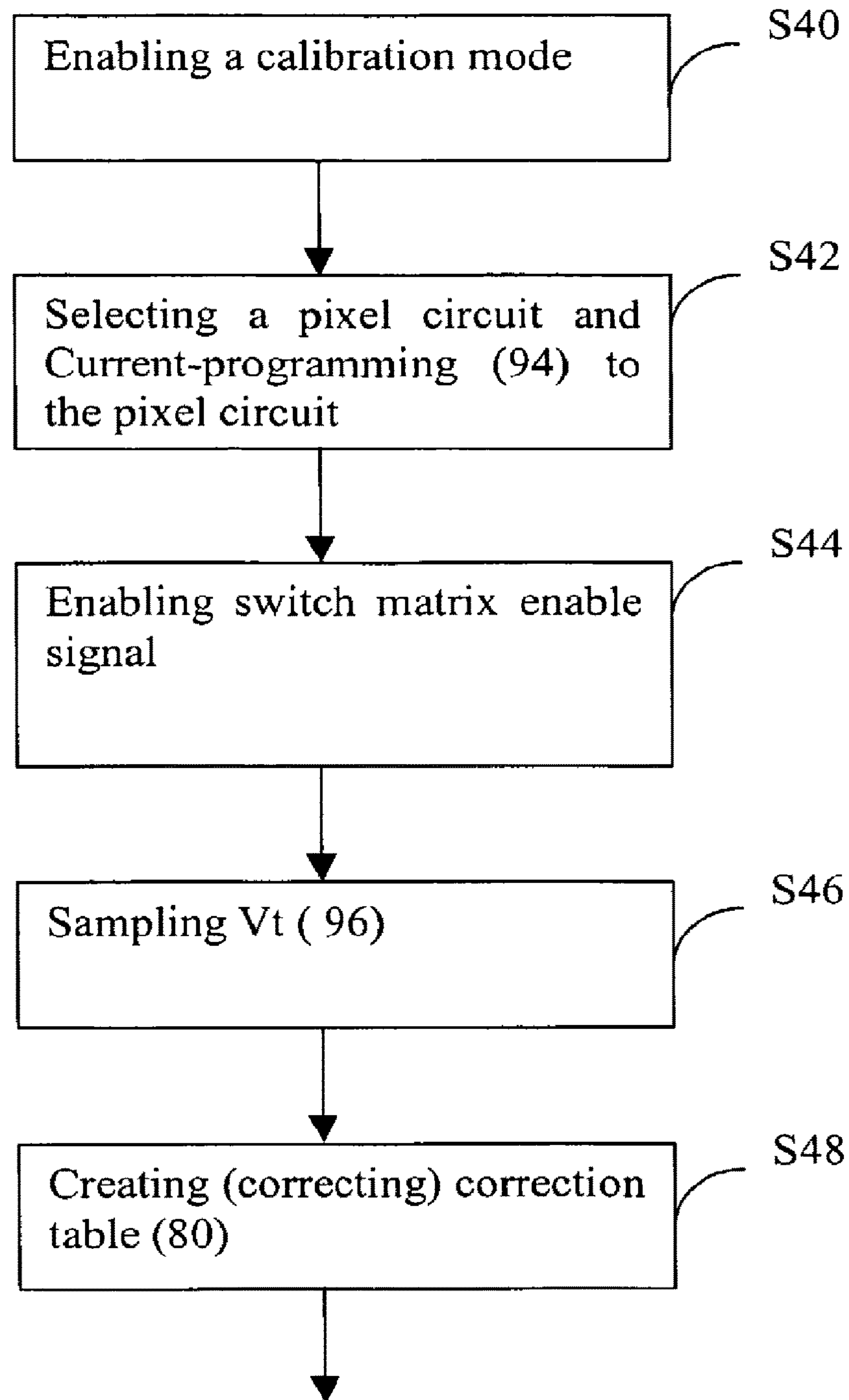


FIG. 13

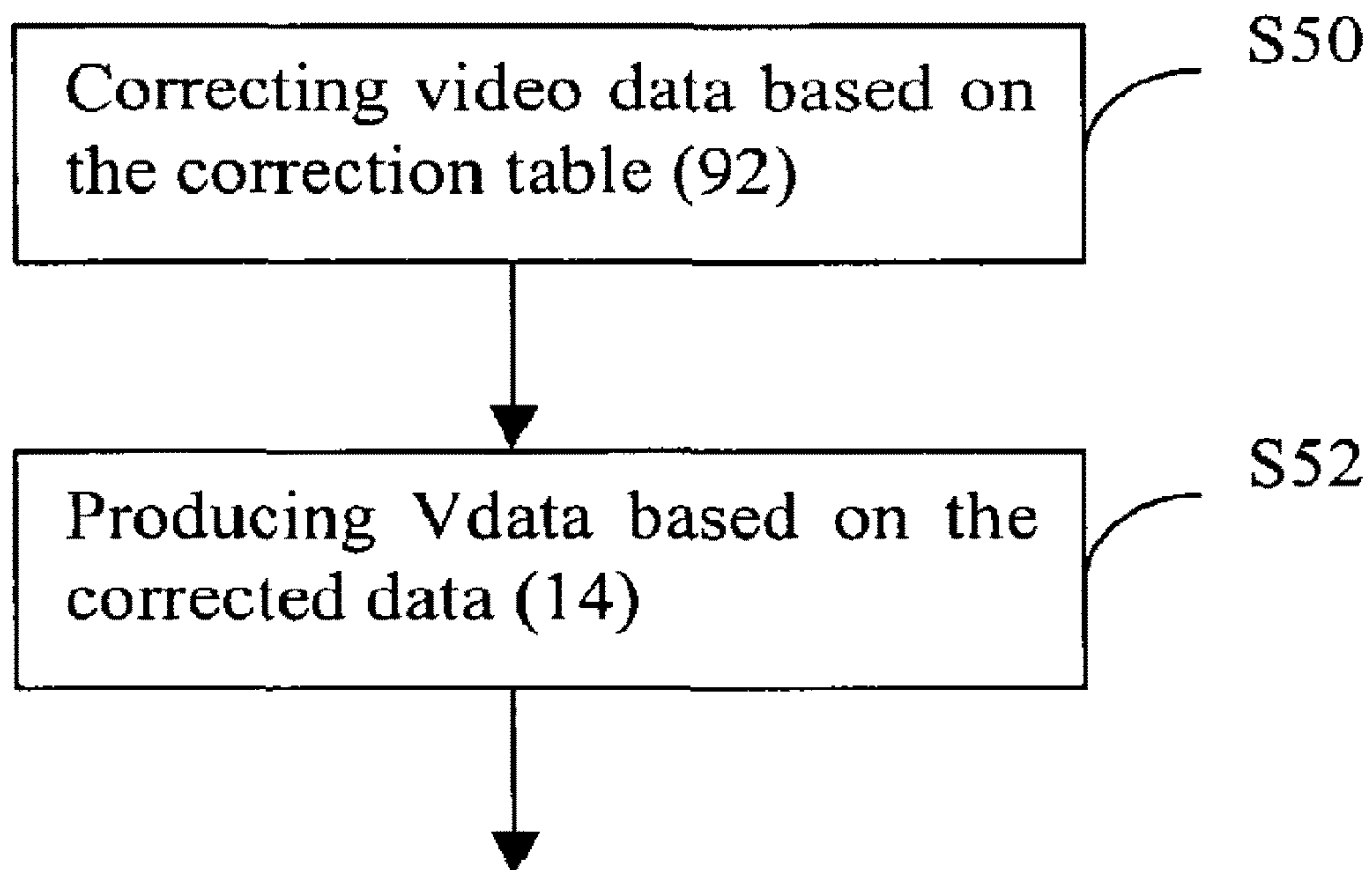


FIG. 14

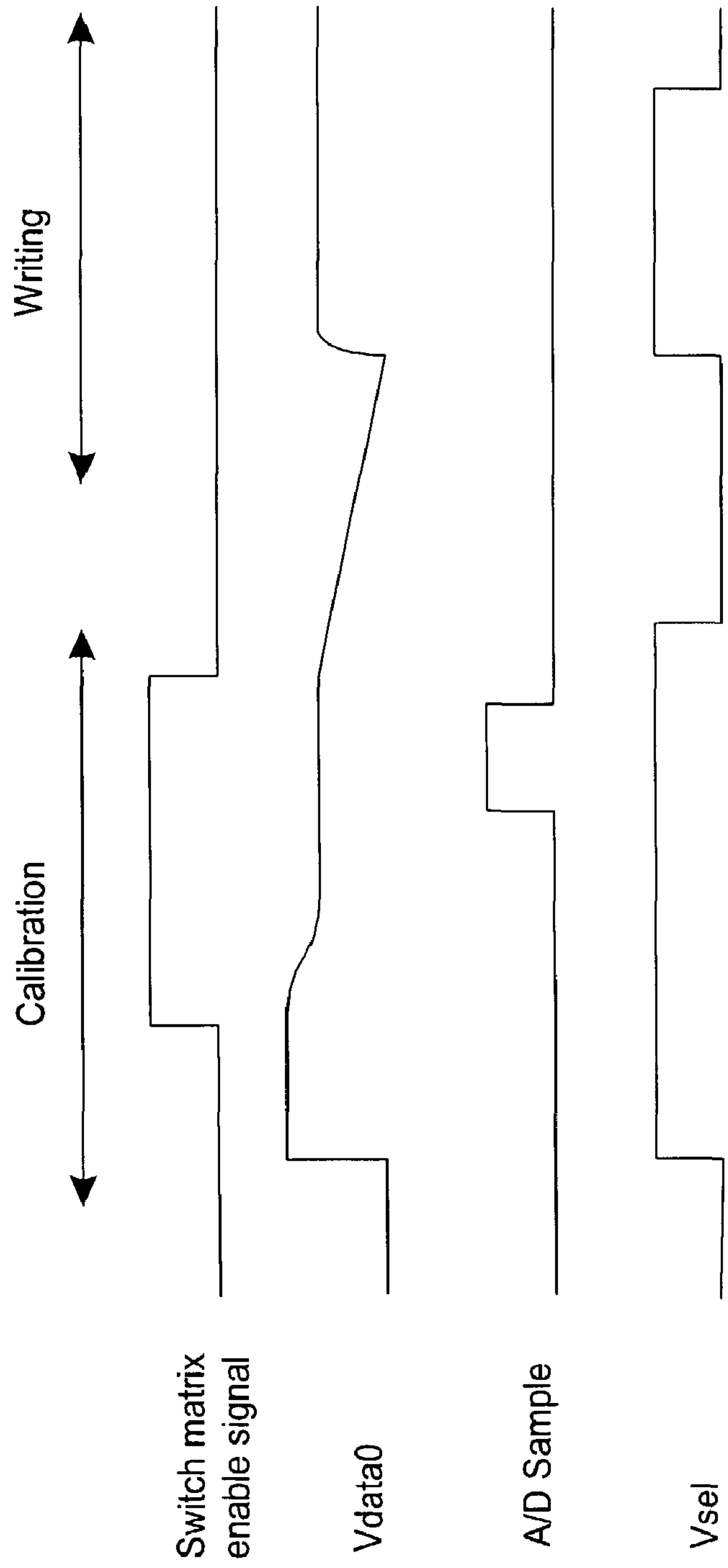


FIG. 15

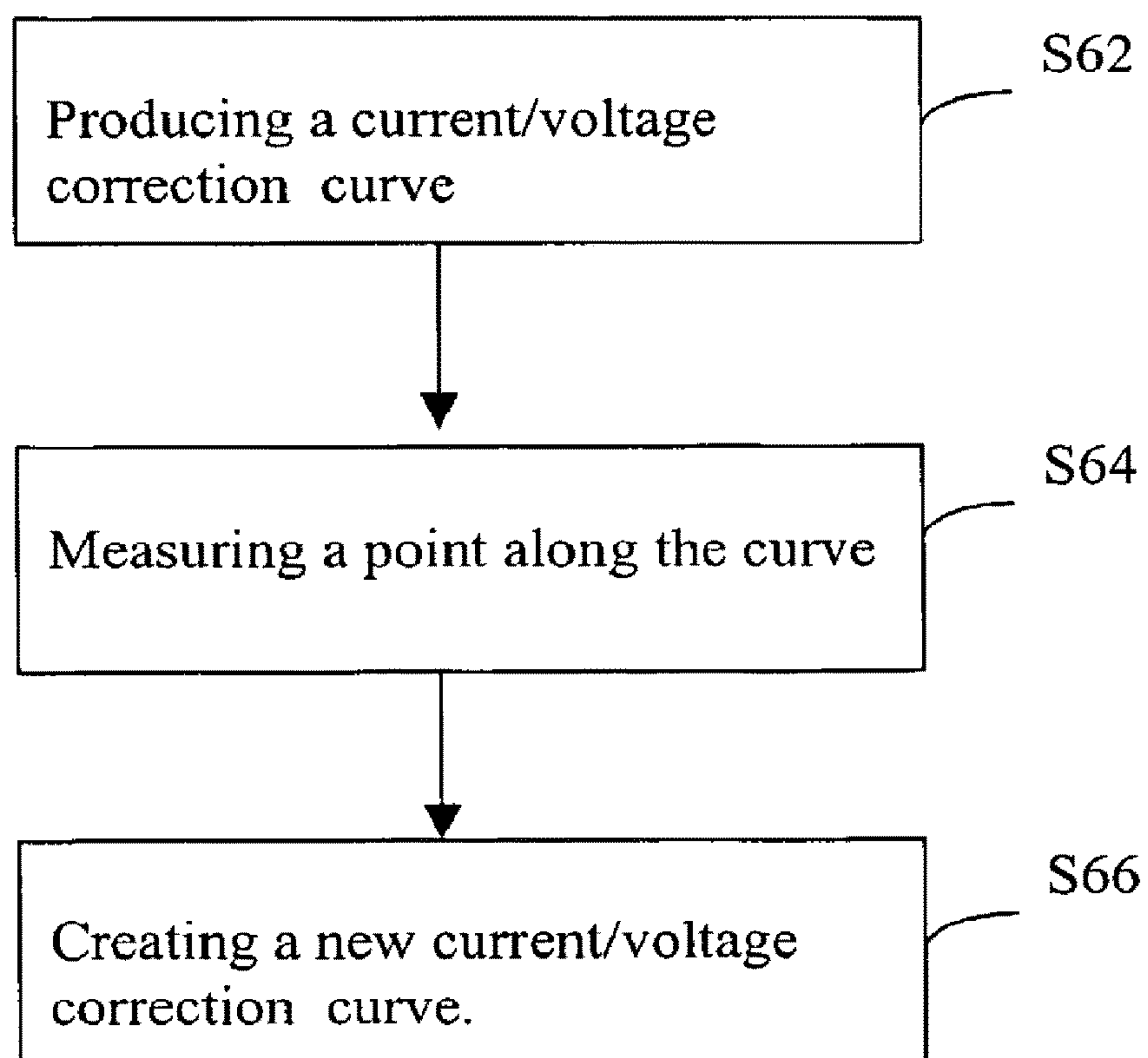


FIG.16

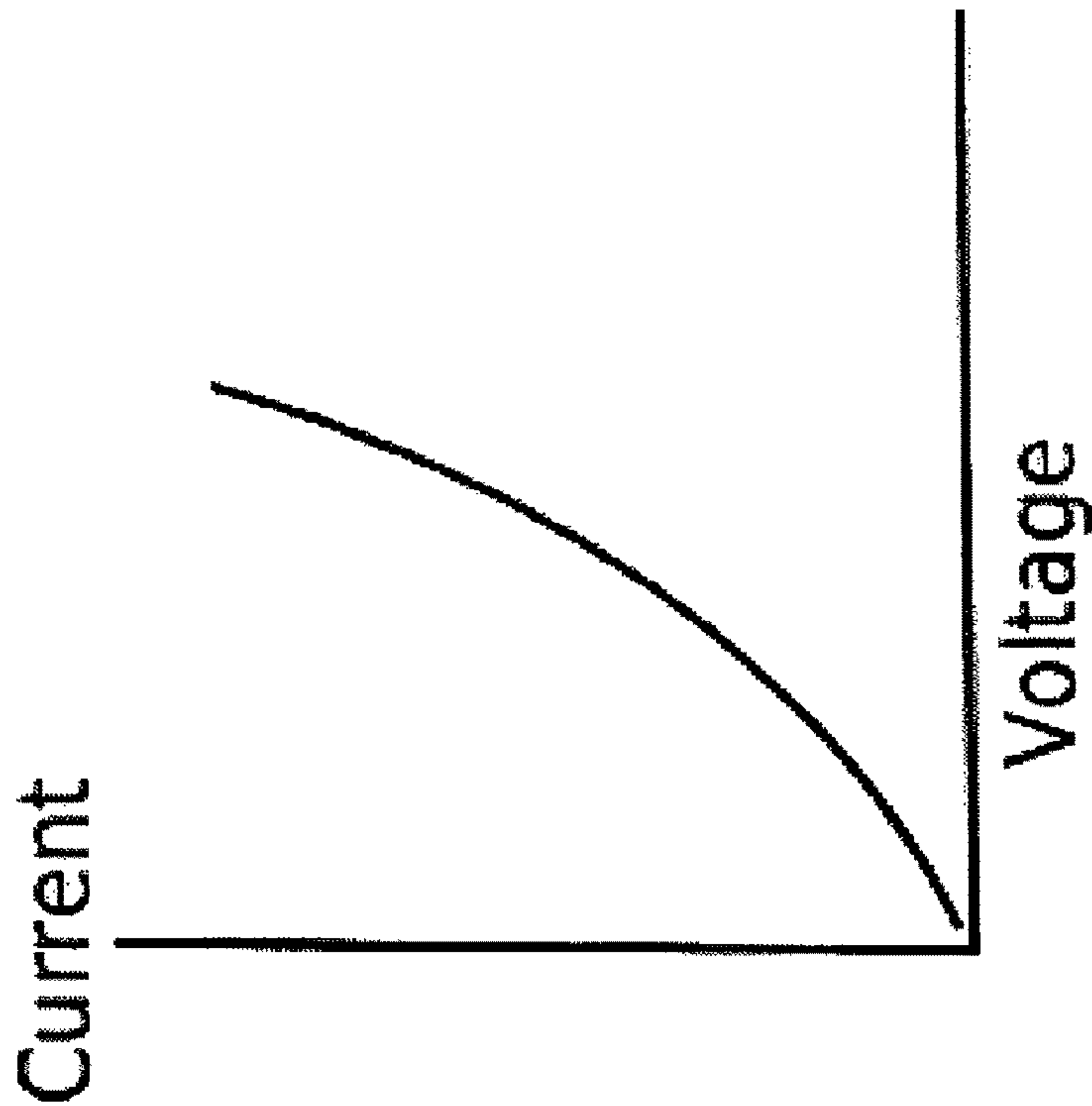


FIG. 17

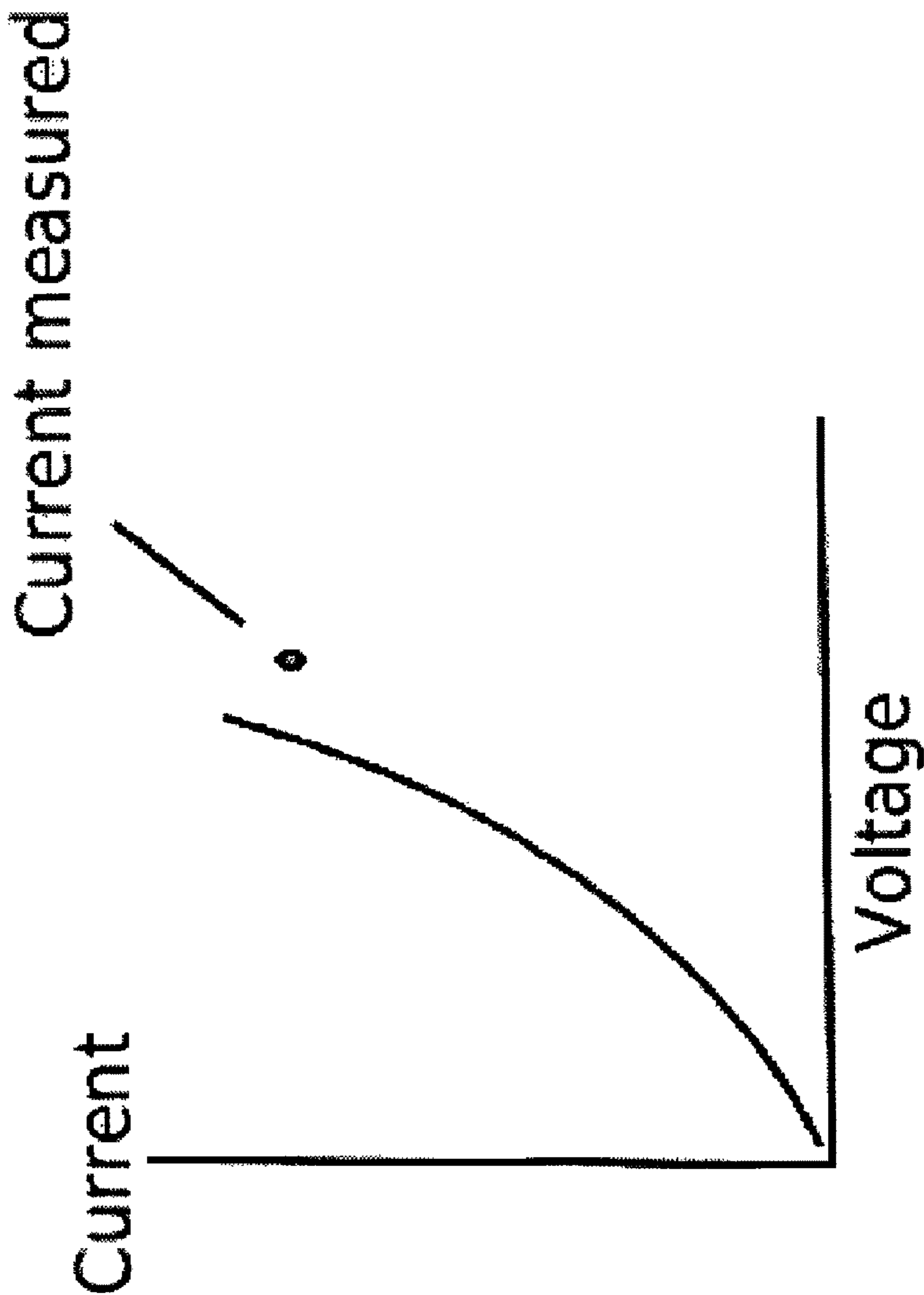


FIG. 18

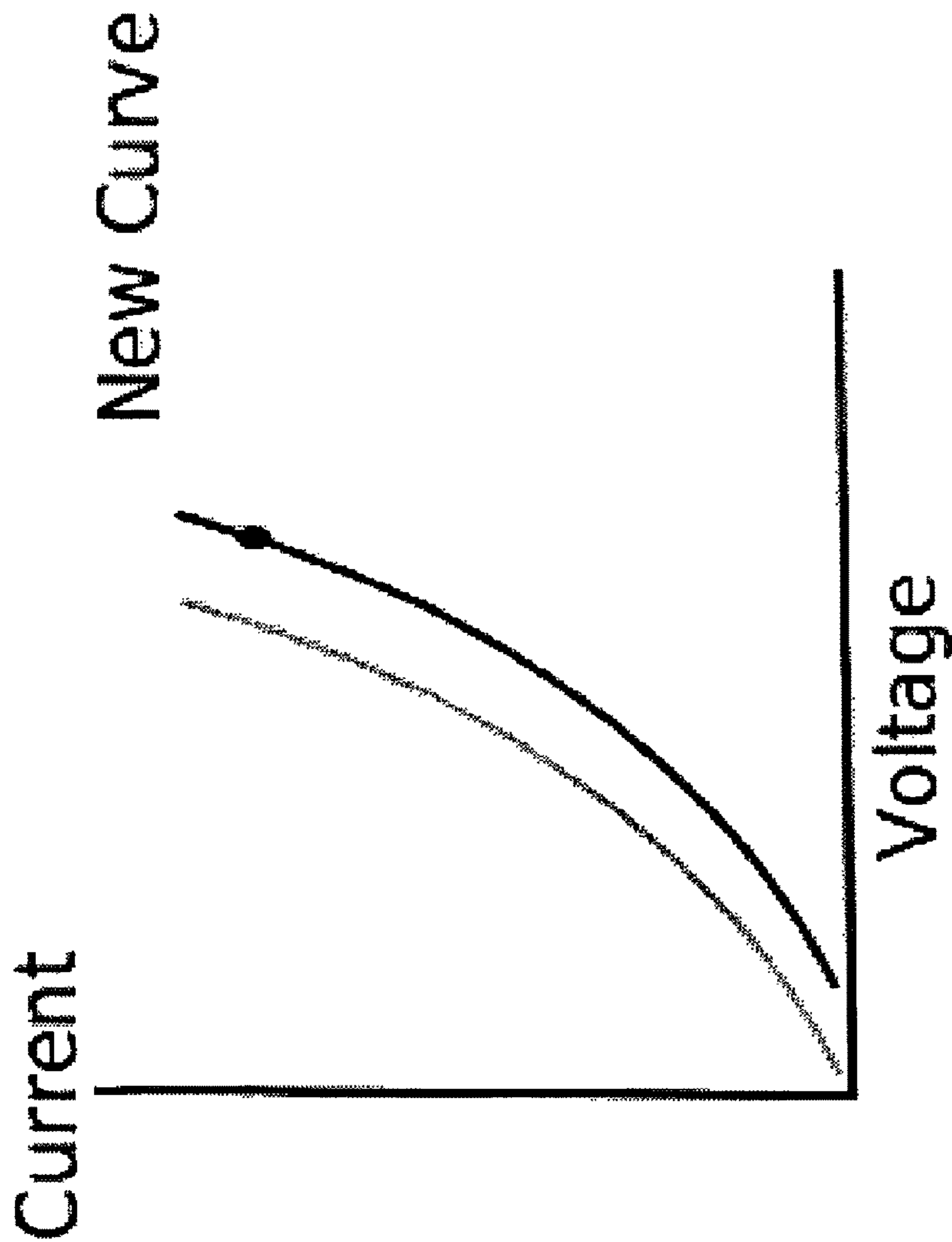


FIG. 19

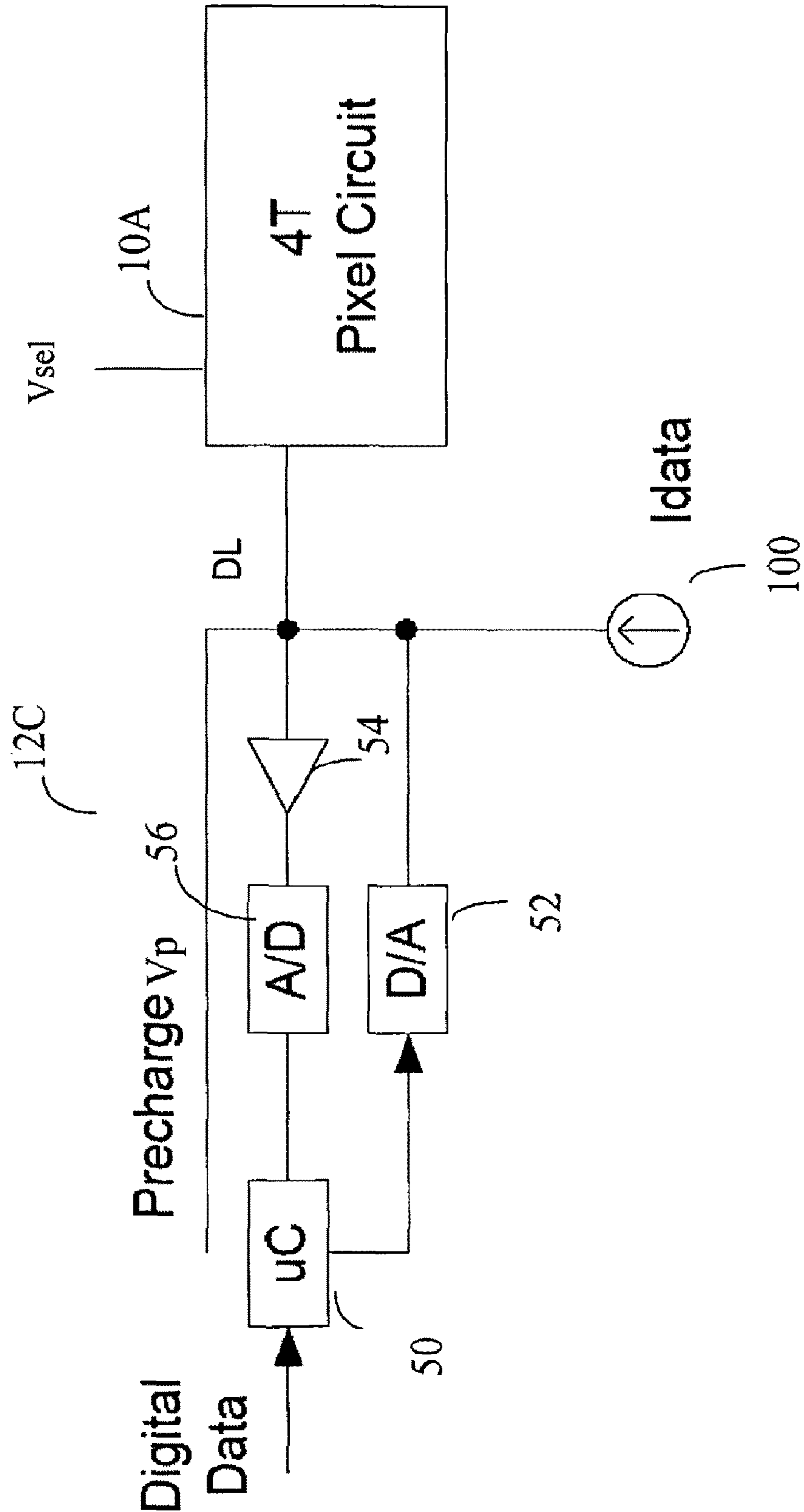


FIG. 20

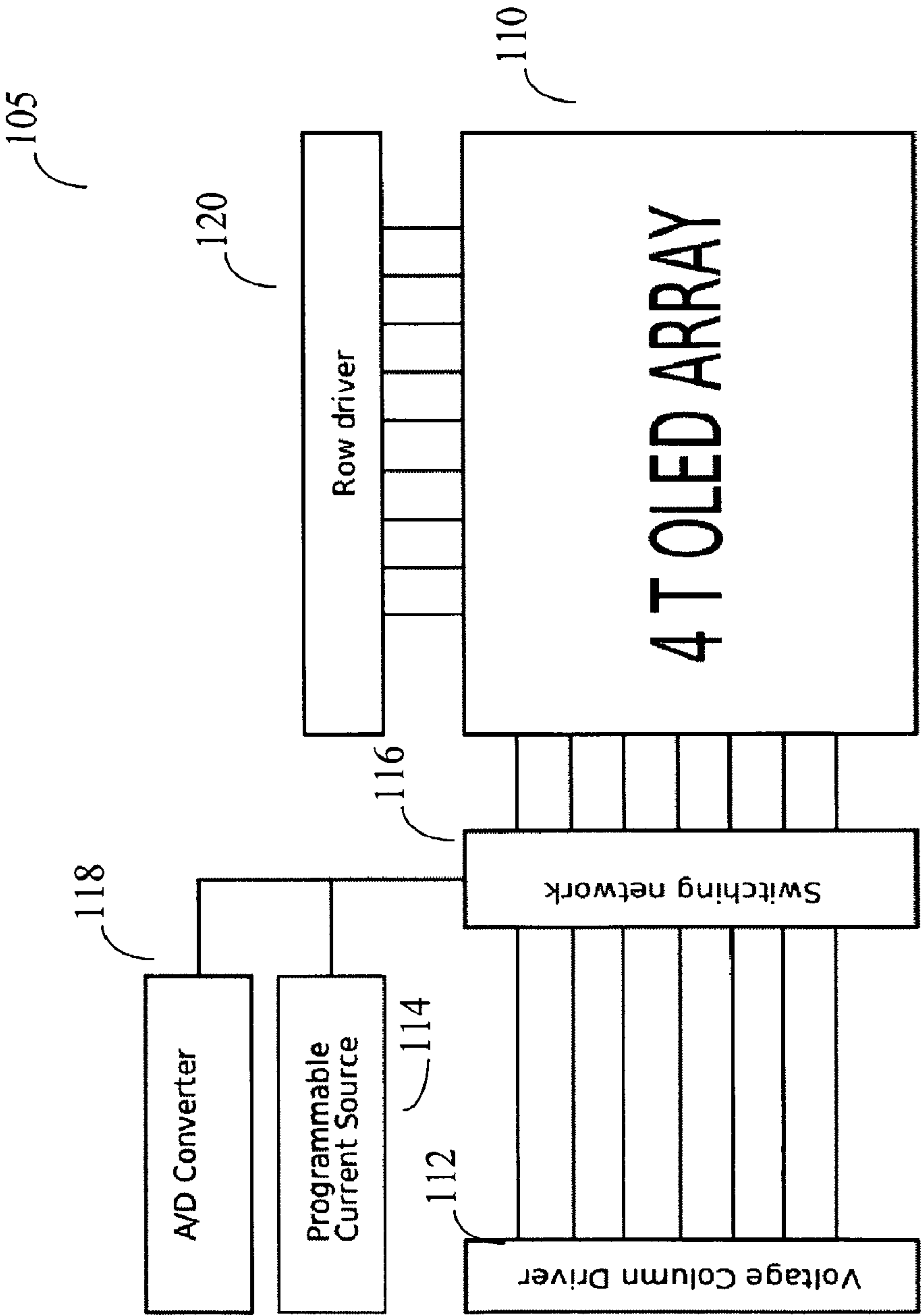


FIG. 21

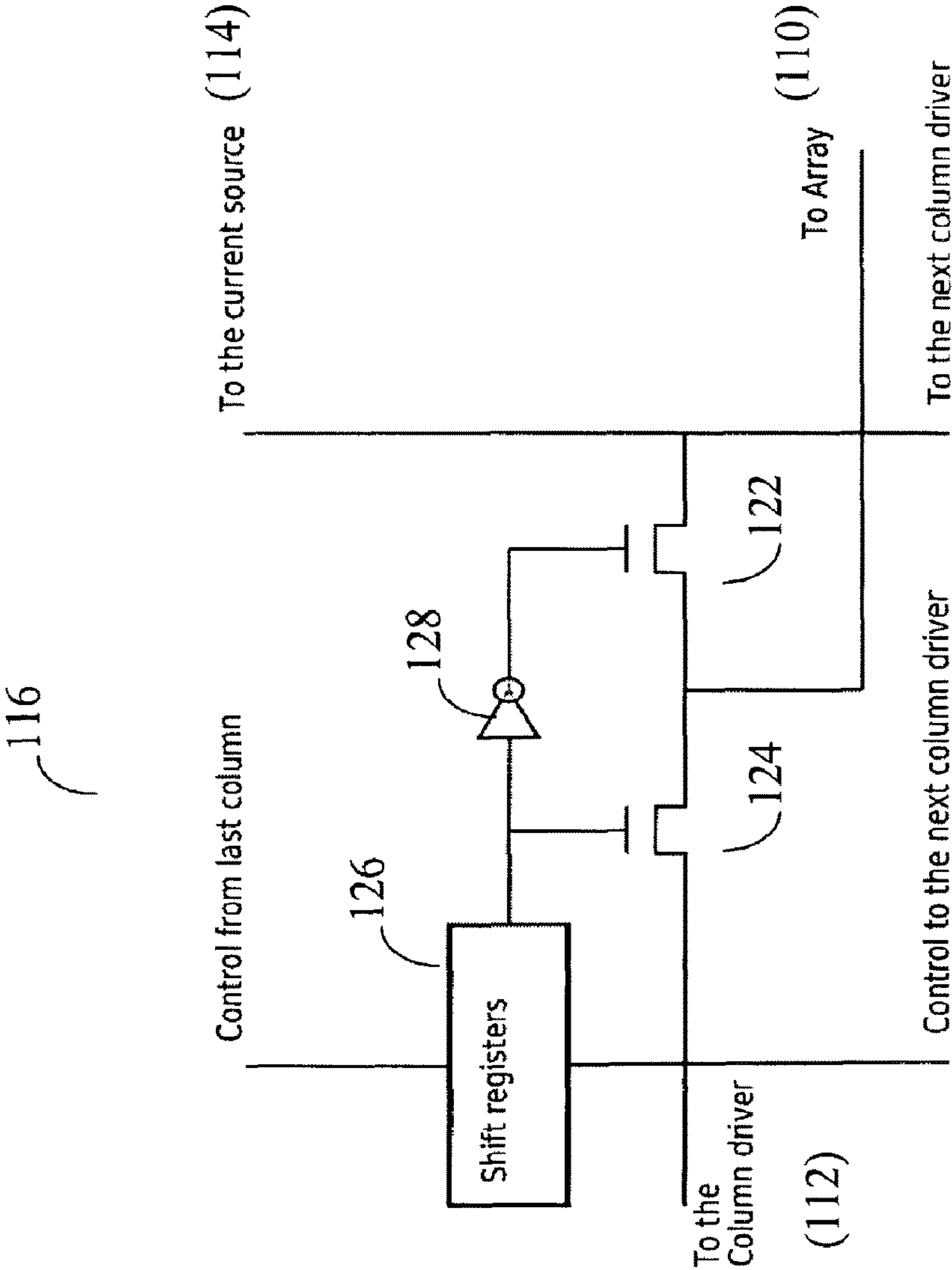


FIG. 22

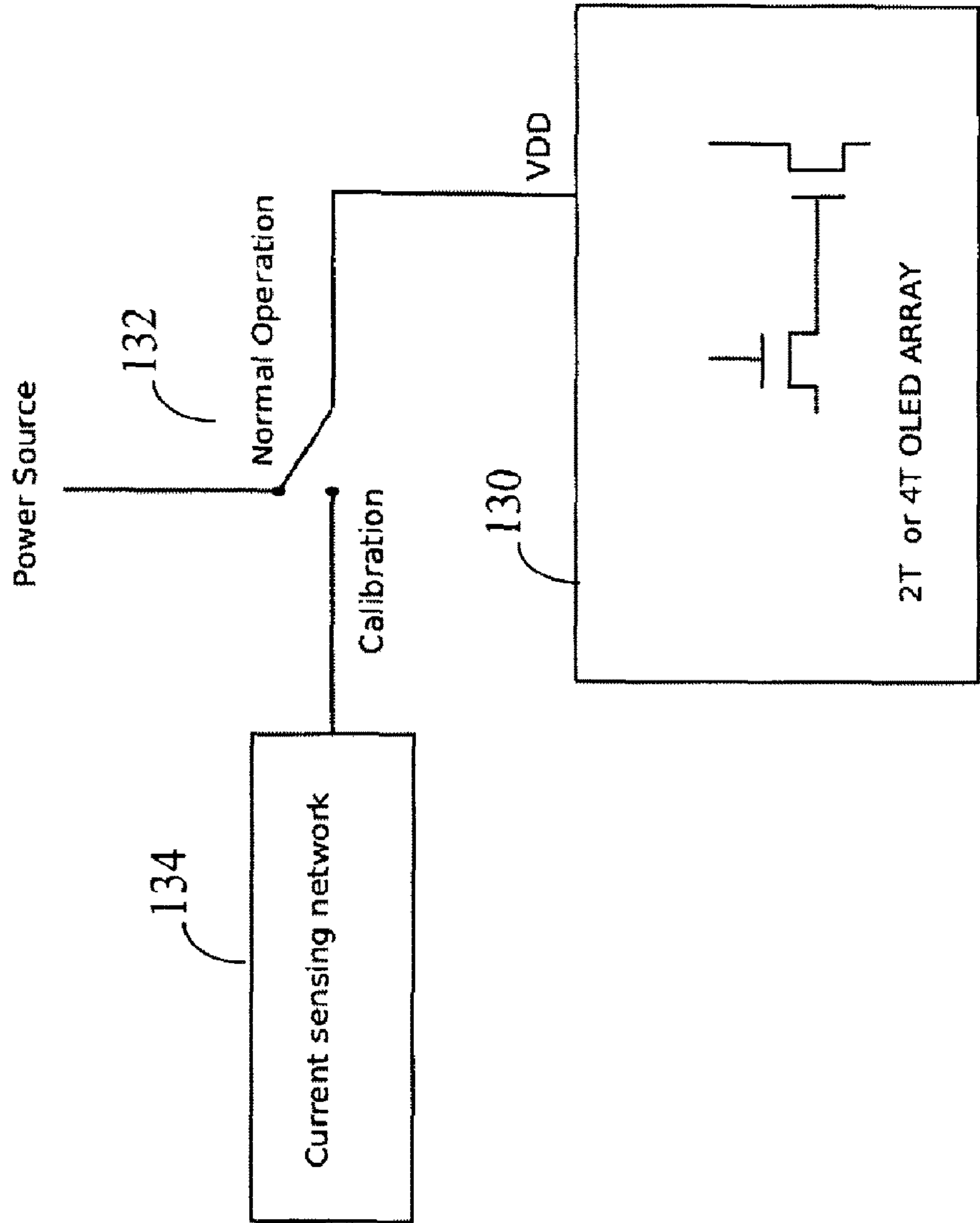


FIG. 23

VOLTAGE-PROGRAMMING SCHEME FOR CURRENT-DRIVEN AMOLED DISPLAYS

Matter enclosed in heavy brackets [] appears in the original patent but forms no part of this reissue specification; matter printed in italics indicates the additions made by reissue; a claim printed with strikethrough indicates that the claim was canceled, disclaimed, or held invalid by a prior post-patent action or proceeding.

Notice: More than one reissue application has been filed for the reissue of U.S. Pat. No. 8,232,939. The reissue applications are (1) Ser. No. 14/090,320, which is an application for reissue of U.S. Pat. No. 8,232,939 and has been reissued as U.S. Pat. No. RE45,291 E, (2) application Ser. No. 14/326,705 (the present application), which is a continuation reissue of U.S. Pat. No. 8,232,939, and (3) application Ser. No. 14/326,677, which is a divisional reissue of U.S. Pat. No. 8,232,939.

CROSS REFERENCE TO RELATED APPLICATIONS

This is a continuation of U.S. patent application Ser. No. 11/571,480, which is a national stage application of international application no. PCT/CA2005/001007, filed Jun. 28, 2005, which claims the benefit of and priority to Canadian Patent Application No. 2,472,671, filed on Jun. 29, 2004, each of these applications being incorporated herein by reference in its entirety.

FIELD OF INVENTION

The present invention relates to a display technique, and more specifically to technology for driving pixel circuits.

BACKGROUND OF THE INVENTION

Active matrix organic light emitting diode (AMOLED) displays are well known in the art. The AMOLED displays have been increasingly used as a flat panel in a wide variety of tools.

The AMOLED displays are classified as either a voltage-programmed display or a current-programmed display. The voltage-programmed display is driven by a voltage-programmed scheme where data is applied to the display as a voltage. The current-programmed display is driven by a current-programmed scheme where data is applied to the display as a current.

The advantage of the current-programming scheme is that it can facilitate pixel designs where the brightness of the pixel remains more constant over time than with voltage programming. However, the current-programming requires longer time of charging capacitors associated with the column.

Therefore, there is a need to provide a new scheme for driving a current-driven AMOLED display, which ensures high speed and high quality.

SUMMARY OF THE INVENTION

The present invention relates to a system and method of driving a pixel circuit in an AMOLED display.

The system and method of the present invention uses Voltage-Programming Scheme For Current-Driven AMOLED Displays.

In accordance with an aspect of the present invention there is provided a system for driving a display which includes a plurality of pixel circuits, each having a plurality of thin film transistors (TFTs) and an organic light emitting diode (OLED), which includes: a voltage driver for generating a voltage to program the pixel circuit; a programmable current source for generating a current to program the pixel circuit; and a switching network for selectively connecting the data driver or the current source to one or more pixel circuits.

In accordance with a further aspect of the present invention there is provided a system for driving a pixel circuit having a plurality of thin film transistors (TFTs) and an organic light emitting diode (OLED), which includes: a pre-charge controller for pre-charging and discharging a data node of the pixel circuit to acquire threshold voltage information of the TFT from the data node; and a hybrid driving circuit for programming the pixel circuit based on the acquired threshold voltage information and video data information displayed on the pixel circuit.

In accordance with a further aspect of the present invention there is provided a system for driving a pixel circuit having a plurality of thin film transistors (TFTs) and an organic light emitting diode (OLED), which includes: a sampler for sampling, from a data node of the pixel circuit, a voltage required to program the pixel circuit; and a programming circuit for programming the pixel circuit based on the sampled voltage and video data information displayed on the pixel circuit.

In accordance with a further aspect of the present invention there is provided a method of driving a pixel circuit having a plurality of thin film transistors (TFTs) and an organic light emitting diode (OLED), which includes the steps of: selecting a pixel circuit and pre-charging a data node of the pixel circuit; allowing the pre-charged data node to be discharged; extracting a threshold voltage of the TFT through the discharging step; and programming the pixel circuit, including compensating a programming data based on the extracted threshold voltage.

This summary of the invention does not necessarily describe all features of the invention.

BRIEF DESCRIPTION OF THE DRAWINGS

These and other features of the invention will become more apparent from the following description in which reference is made to the appended drawings wherein:

FIG. 1 is a block diagram showing a system for driving an AMOLED display in accordance with an embodiment of the present invention;

FIG. 2 is a schematic diagram showing one example of a pixel circuit of FIG. 1;

FIG. 3 is a schematic diagram showing an example of a hybrid driving circuit, which is applicable to FIG. 1;

FIG. 4 is an exemplary flow chart for showing the operation of the hybrid driving circuit of FIG. 3;

FIG. 5 is an exemplary timing chart for showing the operation of the hybrid driving circuit of FIG. 3;

FIG. 6 is a schematic diagram showing a further example of a hybrid driving circuit, which is applicable to FIG. 1;

FIG. 7 is an exemplary flow chart for showing the operation of the hybrid driving circuit of FIG. 6;

FIG. 8 is a schematic diagram showing a further example of a hybrid driving circuit, which is applicable to FIG. 1;

3

FIG. 9 is an exemplary flow chart for showing the operation of the hybrid driving circuit of FIG. 8;

FIG. 10 is an exemplary timing chart for showing the operation of the hybrid driving circuit of FIG. 8;

FIG. 11 is a schematic diagram showing a further example of the pixel circuit of FIG. 1;

FIG. 12 is a block diagram showing a system for driving an AMOLED display in accordance with a further embodiment of the present invention;

FIG. 13 is an exemplary flow chart for showing the operation of the system of FIG. 12;

FIG. 14 is an exemplary flow chart for showing the operation of the system of FIG. 12;

FIG. 15 is an exemplary timing chart for showing the operation of the system of FIG. 12;

FIG. 16 is an exemplary flow chart for a hidden refresh operation of the system of FIG. 12;

FIG. 17 is a diagram showing an example of a sample of the current/voltage correction curve;

FIG. 18 is a diagram showing the current/voltage correction curve of FIG. 17 and an example of a newly measured data point;

FIG. 19 is a diagram showing an example of a new current/voltage correction curve based on the measured point of FIG. 18;

FIG. 20 is a block diagram showing a further example of a programming circuit for implementing a combined current and voltage-programming technique;

FIG. 21 is a block diagram showing a system for driving an AMOLED display in accordance with a further embodiment of the invention;

FIG. 22 is a schematic diagram showing an example of a switch network of FIG. 21; and

FIG. 23 is a schematic diagram showing a system for correcting the current/voltage information of the pixel circuit.

DETAILED DESCRIPTION

Embodiments of the present invention are described using an AMOLED display. Drive scheme described below is applicable to a current programmed (driven) pixel circuit and a voltage programmed (driven) pixel circuit.

In addition, hybrid technique described below can be applied to any existing driving scheme, including a) any drive schemes that use sophisticated timing of the data, select, or power inputs to the pixels to achieve increased brightness uniformity, b) any drive schemes that use current or voltage feedback, c) any drive schemes that use optical feedback.

The light emitting material of the pixel circuit can be any technology, specifically organic light emitting diode (OLED) technology, and in particular, but not limited to, fluorescent, phosphorescent, polymer, and dendrimer materials.

Referring to FIG. 1, there is illustrated a system 2 for driving an AMOLED display 5 in accordance with an embodiment of the present invention. The AMOLED display 5 includes a plurality of pixel circuits. In FIG. 1, four pixel circuits 10 are shown as an example.

The system 2 includes a hybrid driving circuit 12, a voltage source driver 14, a hybrid programming controller 16, a gate driver 18A and a power-supply 18B. The pixel circuit 10 is selected by the gate driver 18A (Vsel), and is programmed by either voltage mode using a node Vdata or current mode using a node Idata. The hybrid driving circuit 12 selects the mode of programming, and connects it to the

4

pixel circuit 10 through a hybrid signal. A pre-charge signal (Vp) is applied to the pixel circuit 10 to acquire threshold Vt information (or Vt shift information) from the pixel circuit 10. The hybrid driving circuit 12 controls the pre-charging, if pre-charging technique is used. The pre-charge signal (Vp) may be generated within the hybrid driving circuit 12, which depends on the operation condition. The power-supply 18B (Vdd) supplies the current required to energize the display 5 and to monitor the power consumption of the display 5.

The hybrid controller 16 controls the individual components that make up the entire hybrid programming circuit. The hybrid controller 16 handles timing and controls the order in which the required functions occur. The hybrid controller 16 may generate data Idata and supplied to the hybrid driving circuit 12. The system 2 may have a reference current source, and the Idata may be supplied under the control of the hybrid controller 16.

The hybrid driver 12 may be implemented either as a switching matrix, or as the hybrid driving circuit(s) of FIG. 3, 6, 8 or 20 or combination thereof.

In the description, Vdata refers to data, a data signal, a data line or a node for supplying the data or data signal Vdata, or a voltage on the data line or the node. Similarly, Idata refers to data, a data signal, a data line or a node for supplying the data or data signal Idata, or a current on the data line or the node. Vp refers to a pre-charge signal, a pre-charge pulse, a pre-charge voltage for pre-charging/discharging, a line or a node for supplying the pre-charge signal, pre-charge pulse or pre-charge voltage Vp. Vsel refers to a pulse or a signal for selecting a pixel circuit or a line or a node for supplying the pulse or signal Vs. The terms "hybrid signal", "hybrid signal node", and "hybrid signal line" may be used interchangeably.

The pixel circuit 10 includes a plurality of TFTs, and an organic light emitting diode (OLED). The TFT may be an n-type TFT or a p-type TFT. The TFT is, for example, but not limited to, an amorphous silicon (a-Si:H) based TFT, a polycrystalline silicon based TFT, a crystalline silicon based TFT, or an organic semiconductor based TFT. The OLED may be regular (P-I-N) stack or inverted (N-I-P) stack. The OLED can be located in the source or the drain of one or more driving TFTs.

FIG. 2 illustrates an example of the pixel circuit 10 of FIG. 1. The pixel circuit of FIG. 2 includes four thin film transistors (TFTs) 20-26, a capacitor Cs 28 and an organic light emitter diode (OLED) 30. The TFT (Tdrive) 26 is a drive TFT that is connected to the OLED 30 and the capacitor Cs 28. The pixel circuit of FIG. 2 is selected by the select line Vsel, and is programmed by a data line DL. The data line DL is controlled by the hybrid signal output from the hybrid driving circuit 12 of FIG. 1.

In FIG. 2, four TFTs are illustrated. However, the pixel circuit 10 of FIG. 1 may include less than four TFTs or more than four TFTs.

In the description, the terms "data line DL" and "data node DL" may be used interchangeably.

Referring to FIGS. 1-2, the data node DL is pre-charged and discharged to acquire the threshold Vt of a drive TFT (e.g., Tdrive 26 of FIG. 2) or the threshold Vt shift. In the description, Vt shift, Vt shift information, Vt, and Vt information may be used interchangeably. The pixel circuit 10 is then consecutively programmed by the source driver 14 using voltage-programming. The acquired Vt shift information is utilized to compensate for degradation of the pixel circuit 10, thus maintaining uniform brightness of the display 5.

5

The process of acquiring V_t starts by applying V_{sel} to T1 20 and T2 22 to the pixel circuit illustrated in FIG. 2. Such action causes the drain and gate of T3 24 to be at the same voltage. This allows the V_t of T3 24 to be extracted by first applying the pre-charge voltage V_p to the data line DL, which is then allowed to be discharged. The rate of discharge is a function of V_t . Thus, by measure of the rate of discharge, V_t can be obtained.

FIG. 3 illustrates an example of a hybrid driving circuit, which is applicable to the hybrid driving circuit 12 of FIG. 1. The hybrid driving circuit 12A of FIG. 3 implements voltage programming technique.

The hybrid driving circuit 12A of FIG. 3 includes a charge programming capacitor C_c 32. The charge programming capacitor C_c 32 is provided between the data line V_{data} and the data node DL. The pre-charge line V_p is also connected to the data node DL.

The hybrid driving circuit 12A is provided to a pixel circuit 10A having four TFTs (such as the pixel circuit of FIG. 2). However, the pixel circuit 10A may include more than four TFTs or less than four TFTs.

The charge programming capacitor C_c 32 is provided to program the pixel circuit 10A with a voltage that is equal to the sum of threshold V_t of the TFT and V_{data} , scaled by a constant K . The constant is determined by the voltage division network formed by the charge storage capacitor (e.g. C_s 28 of FIG. 2) and the charge programming capacitor C_c 32.

FIG. 4 illustrates an exemplary flow chart for showing the operation of the hybrid driving circuit 12A of FIG. 3. At step S10, pre-charge mode is enabled. At step S12, a pixel circuit is selected and pre-charging (V_p) is started. At step S14, V_t acquisition mode is enabled, and at step S16, discharging (V_p) starts. The V_t information is acquired through C_c 32. Then at step S18, writing mode is enabled.

FIG. 5 illustrates an exemplary timing chart for showing the operation of the hybrid driving circuit 12A of FIG. 3. In the drawings, V_{data0} represents voltage at the data node (e.g. DL of FIG. 2) of the pixel circuit; I_{data0} represents current at the data node (e.g. DL of FIG. 2) of the pixel circuit.

The programming procedure starts by selecting the pixel to be programmed with the pulse V_{sel} . At the same time, the pre-charge pulse V_p is applied to the pixel circuit's data input (e.g. DL of FIG. 2).

During the V_t acquisition phase, voltage on the data line (DL) is allowed to be discharged through the pixel circuit, which is in a current mirror connection with the V_{sel} line held high. The data line (DL) is discharged to a certain voltage, and the V_t of a drive TFT is extracted from that voltage. The voltage at V_{data} is at ground.

During the programming (writing) phase, the calculated compensated voltage is applied to the data input line (DL) of the pixel circuit. The programming routine finishes with the lowering of the V_{sel} signal.

The calculated compensated voltage is obtained through analog means of a charge programming capacitor C_c 32. However, any other analog means for obtaining compensated voltage may be used. Further, any (external) digital circuit (e.g. 50 of FIG. 7) may be used to obtain the calculated compensated voltage.

The source driver (14 of FIG. 1) supplies V_{data} to the capacitor C_c 32. When V_{data} is increased from ground to the desired voltage level, the voltage at I_{data} is equal to $(V_t + V_{data}) \cdot K$.

The structure of FIG. 3 is simple, and is easily implemented.

6

FIG. 6 illustrates a further example of a hybrid driving circuit, which is applicable to the hybrid driving circuit 12 of FIG. 1. The hybrid driving circuit 12B of FIG. 6 implements voltage programming technique.

The hybrid driving circuit 12B includes a summer 40, a sample and hold (S/H) circuit 42 and a switching element 44. The S/H circuit 42 samples I_{data} and holds it for a certain period. The summer 40 receives V_{data} and the output of the S/H circuit 42. The switching element 44 connects the output of the summer 40 to the data node DL in response to a programming control signal 46.

The hybrid driving circuit 12B utilizes the summer 40, instead of the charge coupling capacitor C_c 32, to produce programming voltage that is equal to the sum of V_t and V_{data} . As the hybrid driving circuit 12B does not utilize a capacity, programming voltage is not affected by the parasitic capacitance, and it has less charge feed-through effect. As the hybrid driving circuit 12B does not utilize a charge storage capacitor, programming voltage is not affected by the charge storage capacitance. As the hybrid driving circuit 12B does not utilize a charge programming capacitor, it achieves faster V_t acquisition time. Removal of the charge programming capacitor eliminates the charge dependency of the programming scheme. Thus the programming voltage is not affected by the charge being shared between the charge storage capacitor and the parasitic capacitance of the system. This results in a higher effective programming voltage.

FIG. 7 illustrates an exemplary flow chart for showing the operation of the hybrid driving circuit 12B of FIG. 6. During the V_t acquisition mode, the V_t is sampled at step S20, and new data is produced at step S22. When writing mode is enabled, the new data is supplied to the pixel circuit in response to the programming control signal (46) at S24. It is noted that the operation of the system having the hybrid driving circuit 12B is not limited to FIG. 7. The new data may be produced after step S18. The control signal 46 may be enabled before step S18.

During the V_t acquisition cycle, V_{data} is at ground, and the voltage at the data node DL is equal to V_t of the TFT by the pre-charging/discharging operation (V_p). The voltage on the data node DL is sampled and held by the S/H circuit 42. The V_t is provided to the summer 40 through the S/H circuit 42. When V_{data} is increased from ground to the desired voltage level, the summer 40 outputs the sum of V_t and V_{data} . The switch 44 turns on in response to the programming control signal 46. The voltage at the data node DL goes to $(V_t + V_{data})$. Timing chart for showing the operation of the system 2 having the hybrid driving circuit 12B is similar to that of FIG. 5.

FIG. 8 illustrates a further example of a hybrid driving circuit, which is applicable to the hybrid driving circuit 12 of FIG. 1. The hybrid driving circuit 12C of FIG. 8 implements voltage programming technique.

The hybrid driving circuit 13C is a direct digital hybrid driving circuit. The direct digital programming circuit 13C includes a microComputer μC 50 which receives digital data (V_{dada}), a digital to analog (D/A) converter 52, a voltage follower 54 for increasing current without affecting voltage, and an analog to digital (A/D) converter 56.

The threshold V_t of the drive TFT may increase slowly. Thus, it may not be necessary to acquire the threshold V_t of the drive TFT every programming cycle. This effectively hides the V_t acquisition for the majority of the programming cycle. In the direct digital hybrid driving circuit 13C, the threshold V_t acquired from the pixel circuit 10A is digitalized at the A/D converter 56, and is stored in memory contained in the μC 50. The digital data that defines the

brightness of the pixel is added to the V_t in the uC 50. The resulting voltage is then converted back to an analog value at the D/A 52, which is programmed into the pixel circuit 10A. This programming method is designed to compensate for the slow process of the V_t acquisition.

FIG. 9 illustrates an exemplary flow chart for showing the operation of the hybrid driving circuit 12C of FIG. 8. At the V_t acquisition mode, the V_t is sampled and recorded at step S30. When writing mode is enabled, new data is provided based on the recorded data. It is noted that the operation of the system having the hybrid driving circuit 12C of FIG. 8 is not limited to FIG. 9. At the writing mode, the data which have been recorded may be used without implementing the V_t acquisition.

FIG. 10 illustrates an exemplary timing chart for showing the operation of the hybrid driving circuit 12C of FIG. 8. During the V_t acquisition, sampling by the A/D converter 56 is implemented. In a next cycle, the hybrid driving circuit 13C may use the V_t that has been previously acquired and has been recorded in the uC 50.

The conversion of the output on the data node DL by A/D can remove the requirements of having to acquire the V_t every programming cycle. The V_t of the pixel circuit 10A may be acquired once every second or less. Thus, it may acquire V_t for only one row of the display per frame cycle. This effectively increases the amount of time for the pixel programming cycle. Less frequent need of V_t acquisition ensures faster programming time.

In the above description, FIG. 2 is used to describe the pixel circuit 10 of FIG. 1. However, the pixel circuit 10 is not limited to that of FIG. 2. The pixel circuit 10 may be a pixel circuit illustrated in FIG. 11 (J. Kanichi, J.-H. Kim, J. Y. Nahm, Y. He and R. Hattori "Amorphous Silicon Thin-Film Transistor Based Active-Matrix Organic Light Emitting Display" Asia Display IDW 2001 pp. 315). The pixel circuit of FIG. 11 includes four TFTs 64-70, a capacitor C_{ST} 72 and an OLED 74. The TFT 78 is a drive TFT that is connected to the OLED 74 and the capacitor C_{ST} 72. The pixel circuit of FIG. 11 is selected by Vselect1 and Vselect2, and is programmed by Idata. The voltage acquired is a combination of the voltage across the OLED 74 and T3 68. The technique compensates the voltage change of both the V_t and the OLED 74. Idata of FIG. 11 corresponds to the data node DL of FIG. 2.

FIG. 12 illustrates a system for driving an AMOLED display in accordance with a further embodiment of the invention. The system 82 of FIG. 12 includes a hybrid programming circuit having a correction table 80, a source driver 14 for implementing a voltage-programming scheme and a reference current source 94 for implementing a current-programming scheme. The system 82 drives a display having a plurality of pixel circuits using the voltage-programming scheme and the current-programming scheme.

A hybrid controller 98 is provided to control each component. In FIG. 12, the hybrid controller 98 is placed between the A/D converter 96 and the correction table 80, as an example. The hybrid controller 98 is similar to the hybrid controller 16 of FIG. 1.

The pixel circuit driven by the system 82 may be the pixel circuit 10 of FIG. 1, and may be a current programmed pixel circuit or a voltage programmed pixel circuit. The pixel circuit driven by the system 82 may be implemented by FIG. 2 or FIG. 11, however, is not limited to those of FIGS. 2 and 11.

The hybrid programming circuit includes a correction calculation module 92 for correcting data from the data source 90 based on the correction table 80 and an A/D

converter 96. The data corrected by the correction calculation module 92 is applied to the source driver 14. The source driver 14 generates Vdata based on the corrected data output from the correction calculation module 92. Vdata from the source driver 14 and Idata from the reference current source 94 are supplied to the hybrid driver 12.

The data source 90 is, for example, but not limited to, a DVD. The hybrid driver 12 may be implemented either as a switching matrix, or as the digital programming circuit(s) of FIG. 8, 20 or combination thereof. The A/D converter 96 may be the A/D converter 56 of FIG. 8. The system 82 may implement the V_t acquisition technique described above using the A/D converter 96 (56).

The correction table 80 is a lookup table. The correction table 80 records the relationship between current required to program the pixel circuit and voltage necessary to obtain that current. The correction table 80 is built for every pixel in the entire display.

In the description, the relationship between the current required to program the pixel circuit and the voltage necessary to obtain that programming current, is referred to as "current/voltage correction information", "current/voltage correction curve", or "current/voltage information", or "current voltage curve".

In FIG. 12, the correction table 80 is illustrated separately from the correction calculation module 92. However, the correction table 80 may be included in the correction calculation module 92.

The operation of the system of FIG. 12 has two modes, namely display mode and calibration mode. In the display mode, the data from the data source 90 is corrected using the data in the correction table 80, and is applied to the source driver 14. The hybrid driver 12 is not involved in the display mode. In the calibration mode, the current from the reference current source 94 is applied to the pixel circuit, and the voltage associated with the current is read from the pixel circuit. The voltage is converted to a digital data by the A/D converter 96. The correction table 80 is updated with the correct value based on the digital data.

During the display mode, a voltage-programming scheme is implemented. The voltage on the data line (e.g. DL of FIG. 2) of the pixel circuit determines the brightness of the pixels. The voltage required to program the pixel circuit is calculated from the pixel brightness to be displayed (from the incoming video information) combined with the current/voltage correction information stored in the correction table 80. The information on the correction table 80 is combined with incoming video information to ensure that each pixel will maintain a constant brightness over long-term use.

After the display has been used for a fixed period of time, the display enters the calibration mode. The current source 94 is connected to the data input node (DL) of the pixel circuit via the hybrid driver 12. Each pixel is programmed through a current-programming scheme (where the level of current on the data line determines the brightness of the pixel), and the voltage required to achieve that current is read by the A/D converter 96.

The voltage required to program the pixel current is sampled at multiple current points by the A/D converter 96. The multiple points may be a subset of the possible current levels (e.g. 256 possible levels for 8-bit, or 64 levels for 6-bit). This subset of voltage measurements is used to construct the correction table 80 that is interpolated from the measurement points.

The calibration mode may be entered either through user's command or may be combined with the normal display mode so that the calibration takes place during the display refresh period.

In one example, the entire display may be calibrated at once. The display may stop showing incoming video information for a short period of time while each pixel was programmed with a current and the voltage recorded.

In a further example, a subset of the pixels may be calibrated, such as one pixel every fixed number of frames. This is virtually transparent to the user, and the correction information may still be acquired for each pixel.

When a conventional voltage-programming scheme is utilized, a pixel circuit is programmed in an open loop configuration, where there is no feedback from the pixel circuit regarding the threshold voltage shift of the TFTs. When a conventional current-programming scheme is utilized, the brightness of the pixel may remain constant over time. However, the current programming scheme is slow. Thus, the table lookup technique combines the technique of the current-programming scheme with the technique of the voltage-programming scheme. The pixel circuit is programmed with a current through a current-programming scheme. A voltage to maintain that current is read and is stored at a lookup table. The next time that particular level of current is applied to the pixel circuit, instead of programming with a current, the pixel circuit is programmed based on information on the lookup table. Accordingly, it attains the compensation inherent in the current programming scheme while attaining the fast programming time that is only possible with voltage-programming scheme.

In the above description, the correction table (lookup table) **80** is used to correct the current/voltage correction information. However, the system **82** of FIG. **12** may use the lookup table to correct the V_t shift and the current/voltage correction information at the same time in combination with the hybrid driving circuit of FIG. **3**, **6**, **8** or **20**.

For example, several voltage measurements are captured at many different current points by the A/D converter **96** (**56**). The hybrid controller **98** extracts the V_t shift information by extending the voltage versus current curve to zero current point. The V_t shift information is stored in an array of tables (correction table **80**) which is applied to incoming display data.

The uC **50** of FIG. **8** or **20** may utilize the lookup table to generate appropriate voltage and program the pixel circuit.

The hybrid circuits **12A** of FIGS. **3** and **12B** of FIG. **6** may be integrated into the system of FIG. **12**.

FIGS. **13-14** illustrate exemplary flow charts for showing the operation of the system of FIG. **12**. Referring to FIG. **13**, at step **S40**, calibration mode is enabled. At step **S42**, a pixel circuit is selected and current programming is implemented to the selected pixel circuit. At step **S44**, a switch matrix enable signal is enabled. Then the connection to the pixel circuit is changed. The V_t is sampled at step **S46**, and then the correction table is created/corrected at step **S48**. Referring to FIG. **14**, at step **S50**, video data are corrected based on the correction table. Then at step **S52**, new V data is produced based on the corrected data.

It is noted that the writing mode may be implemented based on the previously created correction table without implementing the calibration mode. It is noted that the operation of the system of FIG. **12** is not limited to FIGS. **13-14**.

FIG. **15** illustrates an exemplary timing chart for showing a combination of the V_t shift acquisition and the current/

voltage correction. A switch matrix enable signal in FIG. **15** represents a control signal for the hybrid driver **12** of FIG. **12**.

Referring to FIGS. **12** and **15**, the calibration mode (i.e. the current-programming scheme) is enabled when the switch matrix enable signal is high. The programming mode (i.e. the voltage-programming scheme) is enabled when the switch matrix enable signal is low. However, the calibration mode may be enabled when the switch matrix enable signal is low. The programming mode may be enabled when the switch matrix enable signal is high.

A/D sampling is implemented during the calibration mode. During the calibration mode, the current from the reference current source **94** is applied to the pixel circuit. The voltage on the data input node is converted to a digital voltage by the A/D converter **56**. Based on the digital voltage and current associated with the digital voltage, current/voltage correction information is recorded at the lookup table. The V_t shift information is generated based on the data in the correction table **80** or the output from the A/D converter **96**.

The system **82** of FIG. **12** may implement hidden refresh technique for refreshing current/voltage correction information in addition to the table lookup technique described above.

Under the hidden refresh operation, new current/voltage correction information is constructed while completely hidden from user's perception. This technique utilizes the information that is currently displayed on the screen (i.e. the incoming video data). By obtaining the pixel characteristics from the full calibration routine that has been performed during the manufacturing process of the display, the current/voltage correction information for each pixel in the display is known. During the display's usage, the current/voltage correction curve may shift due to the change in V_t . By measuring a single point along the current/voltage correction curve (which is the data currently displayed, that is part of the video image), a new current/voltage correction curve is extrapolated from the point so that it is fitted to the measured point. Based on the new current/voltage correction curve, the V_t shift information is extracted which is used to compensate for the shift in V_t .

FIG. **16** illustrates an exemplary flow chart for the hidden refresh operation of the system of FIG. **12**. First, a current/voltage correction curve is produced during the calibration process that is implemented during the manufacturing of the display (step **S62**). FIG. **17** illustrates an example of a sample of the current voltage correction curve.

Referring to FIG. **16**, the next step is to measure a point along the curve during the usage of the display. This point can be any point along the curve, so any data that the user currently has on the display can be used for calibration (step **S64**). FIG. **18** illustrates the current voltage correction of FIG. **17** and an example of a newly measured data point.

Referring to FIG. **16**, the last step is to shift the current/voltage correction curve to fit the point of voltage versus current relationship that is measured (step **S66**). FIG. **19** illustrates an example of a new current voltage correction curve based on the measured point of FIG. **18**.

The process associated with FIGS. **17-19** is implemented in the hybrid controller **98** of FIG. **12**.

The system **82** of FIG. **12** may implement a combined current and voltage-programming technique. FIG. **20** illustrates one example of a hybrid driving circuit for implementing the combined current and voltage-programming technique. The hybrid driving circuit of FIG. **20** may be included in the hybrid driver **12** of FIG. **12**.

11

In the hybrid driving circuit of FIG. 20, the digital hybrid driving circuit 12C and a current source 100 are provided to the data line DL of the pixel circuit.

To enhance the circuit's ability to compensate for a change in the current/voltage correction curve due to temperature, threshold voltage shift, or other factors, the pixel circuit programming is divided into two phases.

During the writing mode, the pixel circuit 10A is voltage-programmed first to set the gate voltage of the driving TFT to an approximate value, then followed by a current programming phase. The current programming phase can then fine-tune the output current. The system of FIG. 20 is faster than current programming and has the compensation capabilities of the current programming scheme.

In FIG. 20, the digital hybrid driving circuit 12C is provided. However, the combined current and voltage-programming technique may be implemented by combining the hybrid driving circuit 12A of FIG. 3 or 12B of FIG. 6 with the current source 100. The current source 100 may be the reference current source 94 of FIG. 12.

The system 2 of FIG. 1 may implement the hidden refresh technique described above. The system 2 of FIG. 1 may implement the combined current and voltage-programming technique. The system 2 of FIG. 1 may include the hybrid driving circuit of FIG. 20 to implement the combined current and voltage-programming technique.

Extension of the direct digital programming scheme is now described in detail. The direct digital programming scheme (FIGS. 6, 8 and 20) can be extended to drive an OLED array (e.g. a 4T OLED array) using voltage programmed column drivers, such as those used for driving Active Matrix Liquid Crystal Display (AMLCD), or voltage-programmed Active-Matrix Organic Light Emitting Diode (AMOLED) displays, or any other voltage-output display driver.

FIG. 21 illustrates a system for driving an AMOLED array having a plurality of pixel circuits in accordance with a further embodiment of the invention. The system 105 of FIG. 21 includes a voltage column driver 112, a programmable current source 114, a switching network 116, an A/D converter 118 and a row driver 120.

The voltage column driver 112 is a voltage programmed column driver. Each of the voltage column driver 112 and the row driver 120 may be any driver that has a voltage output, such as those designed for the AMLCD. The voltage column driver 112 and the programmable current source 114 are connected to an OLED array 110 through the switching network 116. The OLED array 110 forms an AMOLED display, and contains a plurality of pixel circuits (such as 10 of FIG. 1). The pixel circuit may be a current programmed pixel circuit or a voltage programmed pixel circuit.

The A/D converter 118 is an interface that allows an analog signal (i.e. current driving the display 110) to be read back as a digital signal. The digital signal associated with the current can then be processed and/or stored. The A/D converter 118 may be the A/D converter 56 of FIGS. 8 and 20. The column driver 112 may be the source driver 14 of FIGS. 1 and 12.

The system 105 of FIG. 21 implements the calibration mode and the display mode as described above.

FIG. 22 illustrates an example of the switch network 116 of FIG. 21. The switching network 116 of FIG. 22 includes two MOSFET switches 122 and 124 that can switch the column of the display (110) from connecting to the column driver (112) to the combination of the current source (114) and the A/D converter (118), and vice versa. A shift register 126 is a source of the digital control signal that controls the

12

operation of the MOS switches 122 and 124. An inverter 128 inverts an output from the shift register 126. Thus, when the switch 122 is on (off), the switch 124 is off (on).

The switching network 116 may be located either off the glass in the column driver (112) or directly on the glass using TFT switches.

Referring to FIGS. 21-22, the system 105 uses only one current source 114. The voltage-programming drivers (such as, AMLCD drivers, or any other voltage-output drivers) drive the rest of the display 110. The switching matrix (switching network 116) allows different pixels within the array of pixels to be connected to a single current source (114) through a time division method. This allows a single current source to be applied to the entire display. This lowers the cost of the driver circuit and speeds up the programming time for the pixel circuit.

The system 105 uses the A/D converter 118 to convert an analog output of the data node (e.g. DL of FIG. 2) of the pixel circuit to digital data. The conversion by the A/D converter 118 removes the requirements of having to acquire the V_t every programming cycle. The V_t of the pixel circuit may be acquired once every few minutes. Thus it may acquire one column of the panel every refresh cycle.

Only one A/D 118 may be implemented for all the columns. The circuit acquires only one pixel per frame refresh. For example, for a 320 by 240 panel, the number of pixels is 76,800. For a frame rate of 30 Hz, the time required to acquire V_t from all pixels for the entire frame is 43 minutes. This may be acceptable for some applications, providing that V_t does not shift substantially in an hour.

The parasitics only affect the amount of time to discharge the capacitor to acquire V_t . Since the circuit is voltage-programmed, it is not affected by the parasitics. Since V_t is only acquired one column per frame time, it can be long. For example, for a display with 320 columns that has a frame rate of 30 Hz, each frame time is 33 mS. For voltage programming, it is possible to program a pixel in 70 μ S. For 320 columns, the time to update the display is 22 mS, which still leave 11 mS to complete a charge/discharge cycle.

The system 105 may implement the lookup table technique to compensate for V_t shift and/or to correct the current/voltage information as described above.

The system 105 may implement the hidden refresh technique to acquire the V_t shift information and current/voltage correction information of each pixel circuit (10) in the display 110. This current/voltage correction information is used to populate a lookup table (e.g. a correction table 80 of FIG. 12) that will then be used to compensate for the degradation in the pixel circuit, which is caused by aging. To reduce cost, the number of current-programmed circuits has been reduced so there is only one per display instead of one per column driver.

The system 105 may implement the combined current and voltage-programming technique as described above.

The current/voltage information of the pixel circuit can be further corrected by implementing a system illustrated in FIG. 23. FIG. 23 illustrates a system for correcting the current/voltage information of the pixel circuit. In FIG. 23, a display 130 is depicted as a 2T or 4T OLED array. However, the display 130 may include a plurality of pixel circuits, each having three or more than four transistors. The display 130 may include voltage-driven pixel circuits or current-driven pixel circuits. The system of FIG. 23 is applicable to the systems 2, 82 and 105 of FIGS. 1, 12 and 22.

As illustrated in FIG. 23, a switch 132 is provided to disconnect the common electrode of the OLED. It is well

13

known that two electrodes are provided for the OLED. One is connected to the pixel circuit, and the other is a common electrode connected to all OLEDs. It is noted that the common electrode may be Vdd or GND depending on the type of OLED. The switch 132 connects the common electrode of the OLED into a current sensing network 134 utilizing a high side common mode sensor (such as, INA168 by TI). The current sensing network 134 measures the current through the common electrode.

During the calibration phase, each pixel is lit individually and the current consumed is acquired by the sensing network 134. The acquired current is used to correct the lookup table (e.g. the correction table 80 of FIG. 12) populated by the direct digital hybrid driving circuit of FIG. 8 or 20.

A dark display current may be acquired to include the effect of dead pixel and leakage current of the array. During this procedure, all pixels are turned off, and the current (i.e. dark display current) is measured.

According to the embodiments of the present invention, the major issue with current-programmed pixel circuits, which is the slow programming time, is solved. The concept of using feedback to compensate the pixel circuit enhances the uniformity and stability of the display while retaining the fast programming capability of the voltage programmed drive scheme.

The present invention has been described with regard to one or more embodiments. However, it will be apparent to persons skilled in the art that a number of variations and modifications can be made without departing from the scope of the invention as defined in the claims.

What is claimed is:

[1. A system for programming at least one pixel circuit in a display, the system comprising:

a voltage driver for generating a voltage to apply to a data node of the at least one pixel circuit to thereby program the at least one pixel circuit according to the generated voltage;

a programmable current source for providing a first current and a second current to apply to the data node of the at least one pixel circuit;

a sampler for reading a first voltage on the data node while the first current is maintained through the at least one pixel circuit via the programmable current source and for reading a second voltage on the data node while the second current is maintained through the at least one pixel circuit via the programmable current source; and

a controller configured to:

generate a voltage versus current relationship for the at least one pixel circuit based on the first current and the second current and based on the sampled first and second voltages,

extract, based on the voltage versus current relationship for the at least one pixel circuit, a voltage corresponding to a zero current level, and

program the at least one pixel circuit via the data node with a programming voltage generated by the voltage driver that is set according to display data and according to the extracted voltage corresponding to the zero current level.]

[2. The system according to claim 1, wherein the at least one pixel circuit is configured to be alternately programmed by a programming current applied to the data node or by a programming voltage applied to the data node.]

[3. The system according to claim 2, wherein the at least one pixel circuit includes a mirror transistor having a gate coupled to a gate terminal of the driving transistor, the at least one pixel circuit configured such that the data node is

14

coupled to a gate terminal of the mirror transistor via one or more switch transistors, the applied current being conveyed via the one or more switch transistors through the mirror transistor while the gate terminal of the mirror transistor adjusts to a voltage for maintaining the applied current through the mirror transistor.]

[4. The system according to claim 3, wherein the one or more switch transistors include a first switch transistor and a second transistor,

the first switch transistor operated according to a select signal and configured to couple the data node to the gate terminal of the mirror transistor while the first switch transistor is switched on,

the second switch transistor operated according to the select signal and configured to couple the data node to a drain or a source terminal of the mirror transistor while the second switch transistor is switched on.]

[5. The system according to claim 2, wherein the at least one pixel circuit includes one or more switch transistors configured to couple the data node to a drain or a source terminal of the driving transistor while the programming current is applied to the at least one pixel circuit via the data node,

the one or more switch transistors further configured to couple the data node to a gate terminal of the driving transistor while the programming current is applied, such that the gate terminal of the driving transistor adjusts to a voltage for maintaining the applied current through the driving transistor,

the one or more switch transistors further configured to couple the data node to a gate terminal of the driving transistor while the programming voltage is applied to the at least one pixel circuit via the data node.]

[6. The system according to claim 1, wherein the sampler includes an analog to digital converter configured to capture digital information indicative of the first and second voltages on the data node.]

[7. The system according to claim 6, further comprising a memory for storing the digital information indicative of the first and second voltages, the digital information being stored in a lookup table that associates the first and second voltages with the first and second currents to thereby characterize the voltage versus current relationship of the at least one pixel circuit.]

[8. The system according to claim 1, wherein the controller is further configured to instruct the voltage driver to set the programming voltage for the at least one pixel circuit by adding the voltage corresponding to the zero current level to a voltage indicated by the display data.]

[9. The system according to claim 1, wherein the at least one pixel circuit is a plurality of pixel circuits arranged in an array of rows and columns, each of the plurality of pixel circuits having a data node coupled to a data line, and wherein the programmable current source is configured to generate a plurality currents to apply to each of the plurality of pixel circuits and the sampler is configured to read a corresponding plurality of voltages for each of the plurality of pixel circuits while each of the plurality of currents is maintained through respective ones of the plurality of pixel circuits.]

[10. The system according to claim 1, wherein the controller is configured to extract the threshold voltage of the driving transistor of the at least one pixel circuit by extending the voltage versus current relationship for the at least one pixel circuit to the zero current level and determining the voltage corresponding to the zero current level, the voltage

15

corresponding to the zero current level providing an estimate of the threshold voltage of the driving transistor of the at least one pixel circuit.]

[11. The system according to claim 1, further comprising a memory communicatively coupled to the controller for digitally storing digital information indicative of the first and second voltages.]

[12. The system according to claim 1, wherein the at least one pixel circuit includes an organic light emitting diode for emitting light according to the display data and one or more thin film transistors for conveying a current through the organic light emitting diode according to the display data.]

[13. A method of operating a display having at least one pixel circuit, the at least one pixel circuit having a light emitting device coupled in series with a driving transistor configured to convey a driving current through the light emitting device according to display information, the at least one pixel circuit configured to be alternately programmed according to the display information by a programming current applied to a data node of the at least one pixel circuit or by a programming voltage applied to the data node, the method comprising:

applying a first current to the data node of the at least one pixel circuit;

reading a first voltage on the data node while the first current is maintained through the at least one pixel circuit;

applying a second current to the data node of the at least one pixel circuit;

reading a second voltage on the data node while the second current is maintained through the at least one pixel circuit;

storing digital information indicative of the first and second voltages such that the first and second voltages are associated with the first and second currents;

generating a voltage versus current relationship for the at least one pixel circuit based on the first and second voltages and the first and second currents;

extracting, based on the generated voltage versus current relationship for the at least one pixel circuit, a voltage corresponding to a zero current level; and

programming the at least one pixel circuit by applying, to the data node of the at least one pixel circuit, a programming voltage that is based on the display data and the voltage corresponding to the zero current level.]

[14. The method according to claim 13, wherein the at least one pixel circuit is at least one of a plurality of pixel circuits arranged in an array of rows and columns in the display, and wherein the applying the first and second current, the reading the first and second voltages, the storing, the generating, and the extracting are applied to each of the plurality of pixel circuits such that voltages corresponding to the zero current level are extracted for each of the plurality of pixel circuits.]

[15. The method according to claim 14, wherein the voltage corresponding to the zero current level is an estimate of a threshold voltage of the driving transistor in the at least one pixel circuit, and wherein the programming is applied to each of the plurality of pixel circuits based on the display data for each of the plurality of pixel circuits and based on the estimate of the threshold voltage of the driving transistor for each of the plurality of pixel circuits such that the display is operated to compensate for the threshold voltages of the driving transistors in each of the plurality of pixel circuits.]

[16. The method according to claim 13, wherein the storing is carried out by digitally storing the digital infor-

16

mation indicative of the first and second voltages in a lookup table associated with the at least one pixel circuit.]

[17. The method according to claim 13, wherein the applying the first current and the applying the second current are performed during a calibration mode of the display that is distinct from a normal display mode, the calibration mode being a period during which images are not shown on the display.]

[18. The method according to claim 13, wherein at least one of the first current or the second current is a programming current applied to the at least one pixel circuit during a programming operation of a normal display mode to program the at least one pixel circuit to emit light according to the display information.]

[19. The method according to claim 13, wherein the at least one pixel circuit is at least one of a plurality of pixel circuits arranged in an array of rows and columns in the display, and wherein at least one of the first current or the second current is a programming current applied to the at least one pixel circuit during a programming operation of a normal display mode while others of the plurality of pixel circuits are voltage programmed with programming voltages, thereby hiding the applying the at least one of the first current or the second current to the at least one pixel circuit.]

[20. The method according to claim 13, further comprising:

responsive to the extracting, applying a third current to the data node of the at least one pixel circuit;

reading a third voltage on the data node while the third current is maintained through the at least one pixel circuit;

storing digital information indicative of the third voltage such that the third voltage is associated with the third current;

updating the voltage versus current relationship for the at least one pixel circuit based on at least the third voltage and the third current;

extracting, based on the updated voltage versus current relationship for the at least one pixel circuit, a voltage corresponding to a zero current level, the voltage corresponding to the zero current level being an updated estimate of a threshold voltage of the driving transistor in the at least one pixel circuit; and

programming the at least one pixel circuit to compensate for the threshold voltage of the driving transistor by applying, to the data node of the at least one pixel circuit, a programming voltage that is based on the display data and the updated estimated threshold voltage.]

[21. A system for programming at least one pixel circuit in a display, the system comprising:

a voltage driver for generating a voltage to apply to a data node of the at least one pixel circuit to thereby program the at least one pixel circuit according to the generated voltage;

a programmable current source for providing a first current to apply to the data node of the at least one pixel circuit;

a sampler for reading a first voltage on the data node while the first current is maintained through the at least one pixel circuit via the programmable current source; and

a controller configured to: receive calibration data indicative of a voltage versus current relationship for the at least one pixel circuit;

17

generate an updated voltage versus current relationship for the at least one pixel circuit based on the first current and the first voltage and based on the received calibration data,

extract, based on the updated voltage versus current relationship for the at least one pixel circuit, a voltage corresponding to a zero current level, and

program the at least one pixel circuit via the data node with a programming voltage generated by the voltage driver that is set according to display data and according to the extracted voltage corresponding to the zero current level.]

[22. The system according to claim 21, wherein the first current is a programming current applied to the at least one pixel circuit during a programming operation of a normal display mode to program the at least one pixel circuit to emit light according to the display information.]

[23. The system according to claim 21, wherein the at least one pixel circuit is configured to be alternately programmed by a programming current applied to the data node or by a programming voltage applied to the data node.]

[24. The system according to claim 21, wherein the at least one pixel circuit is a plurality of pixel circuits arranged in an array of rows and columns, each of the plurality of pixel circuits having a data node coupled to a data line, and wherein the programmable current source is configured to generate a plurality currents to apply to each of the plurality of pixel circuits and the sampler is configured to read a corresponding plurality of voltages for each of the plurality of pixel circuits while each of the plurality of currents is maintained through respective ones of the plurality of pixel circuits.]

[25. The system according to claim 21, wherein the sampler includes an analog to digital converter configured to capture digital information indicative of the first and second voltages on the data node.]

[26. The system according to claim 25, further comprising a memory for storing the digital information indicative of the first voltage, the digital information being stored in a lookup table that associates the first voltage with the first current to thereby characterize the voltage versus current relationship of the at least one pixel circuit.]

[27. The system according to claim 21, wherein the at least one pixel circuit includes an organic light emitting diode for emitting light according to the display data and one or more thin film transistors for conveying a current through the organic light emitting diode according to the display data.]

[28. A method of operating a display having at least one pixel circuit, the at least one pixel circuit having a light emitting device coupled in series with a driving transistor configured to convey a driving current through the light emitting device according to display information, the at least one pixel circuit configured to be alternately programmed according to the display information by a programming current applied to a data node of the at least one pixel circuit or by a programming voltage applied to the data node, the method comprising:

applying a first current to the data node of the at least one pixel circuit;

reading a first voltage on the data node while the first current is maintained through the at least one pixel circuit;

storing digital information indicative of the first voltage such that the first voltage is associated with the first current;

18

receiving calibration data indicative of a voltage versus current relationship for the at least one pixel circuit; generating an updated voltage versus current relationship for the at least one pixel circuit based on the first voltage, the first current, and the received calibration data;

extracting, based on the updated voltage versus current relationship for the at least one pixel circuit, a voltage corresponding to a zero current level; and

programming the at least one pixel circuit by applying, to the data node of the at least one pixel circuit, a programming voltage that is based on the display data and the voltage corresponding to the zero current level.]

[29. The method according to claim 28, wherein the at least one pixel circuit is at least one of a plurality of pixel circuits arranged in an array of rows and columns in the display, and wherein the applying the first current, the reading the first voltage, the storing, the receiving, the generating, and the extracting are applied to each of the plurality of pixel circuits such that voltages corresponding to the zero current level are extracted for each of the plurality of pixel circuits.]

[30. The method according to claim 29, wherein the voltage corresponding to the zero current level is an estimate of a threshold voltage of the driving transistor in the at least one pixel circuit, and wherein the programming is applied to each of the plurality of pixel circuits based on the display data for each of the plurality of pixel circuits and based on the estimate of the threshold voltage of the driving transistor for each of the plurality of pixel circuits such that the display is operated to compensate for the threshold voltages of the driving transistors in each of the plurality of pixel circuits.]

31. *A method of calibrating a display panel having a plurality of pixel circuits, each of the pixel circuits including a drive transistor coupled to an organic light emitting device, comprising:*

measuring a degradation of each pixel circuit of a subset of the pixel circuits during a frame while displaying a video image with the pixel circuits on the display panel; extracting, for each of the pixel circuits of the subset, a current/voltage point for the pixel circuit from the degradation measurement;

determining, for each of the pixel circuits of the subset, corresponding compensation information from a fitting of a previously stored voltage versus current relationship for the pixel circuit to the extracted current/voltage point for the pixel circuit; and

compensating each of the pixel circuits of the subset based on the respective compensation information for each of the pixel circuits of the subset.

32. *The method of claim 31, wherein each of the pixel circuits are programmed using current, while the degradation measurement is a voltage measurement.*

33. *The method of claim 31, wherein the measuring is carried out without stopping video information from being displayed on the display panel.*

34. *The method of claim 33, wherein the measuring is carried out during a refresh period of the display panel.*

35. *The method of claim 31, wherein the measuring, extracting, and determining are carried out externally from the pixel circuit.*